

# **BG96Hardware Design**

#### **LTEModule Series**

Rev. BG96\_Hardware\_Design\_V1.4

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## **About the Document**

## **History**

Revision	Date	Author Description	
		Lyndon LIU/	
1.0	2017-08-04	Daryl DU	Initial
1.1	2017-08-31	Daryl DU	<ol> <li>Modified GSM features in Table 2.</li> <li>Added a note for e-I-DRX in Chapter 3.3.</li> <li>Elaborated the description of e-I-DRX in Chapter 3.4.3.</li> <li>Updated RF receiving sensitivity in Chapter 6.6.</li> </ol>
1.2	2017-12-22	Lyndon LIU/ Daryl DU	<ol> <li>Added the storage temperature of the module in Table 2 and Chapter 6.3.</li> <li>Updated transmitting power values in Table 2.</li> <li>Added the description of sleep mode in Table 5 and Chapter 3.4.4.</li> <li>Added the description of ADC interfaces in Chapter 3.16.</li> <li>Updated the GNSS performance in Table 21.</li> <li>Updated the peak supply current values in Table 28.</li> <li>Updated the current consumption valuesin Chapter 6.4.</li> <li>Updated RF output power values inTable 34.</li> <li>Updated LTE Cat NB1 RF receiving sensitivityvalues (without repetitions) in Table 35.</li> <li>Updated the recommended footprintin Chapter 7.2.</li> </ol>
1.3	2018-07-12	Lyndon LIU/ Daryl DU/	<ol> <li>Updated the timing of turning on module in Figure 8.</li> <li>Updated the USB interfacereference design(Figure 15).</li> </ol>
		Hyman	<ul><li>3. Added the description of GPIO interfaces (Chapter 3.17).</li><li>4. Updated GNSS performance parameters in Table 25.</li></ul>
		DING	5. Updated the GNSS antenna interface reference design (Figure 27).



			6. Updated GNSS current consumption parameters in Table 35.
			7. Updated the module's baking temperatureand baking hours in Chapter 8.1.
1.4	2019-03-13	Lyndon LIU/ Rex WANG	
			<ul><li>14. Added B25 output power in Table 36.</li><li>15. Updated BG96 and added BG96-Mconducted RF receiving sensitivity in Chapter 6.6.</li><li>16. Updated the reel packaging info in Table 40.</li></ul>



## **Contents**

Ab	oout the Document		2
Со	ontents		4
Tal	ble Index		6
Fig	gure Index		8
1	Introduction		9
	1.1. Safety Information		10
	1.2. FCC/ISED Regulatory notices		12
2	Product Concept		14
	2.1. General Description		14
	2.2. Key Features		15
	2.3. Functional Diagram		17
	2.4. Evaluation Board		18
3	Application Interfaces		20
	3.1. Pin Assignment		21
	3.2. Pin Description		23
	3.3. Operating Modes		30
	<u> </u>		
	•	SM)	
		RX(e-I-DRX)	
	·		
		1	
		Dly	
	• •	DIY	
		he PWRKEY Pin	
	•	TO T WITH THE	
		Jsing the PWRKEY Pin	
		Jsing AT Command	
	3.8. (U)SIM Interface		42
	3.9. USB Interface		45
	3.10. UART Interfaces		46
	3.11. PCM* and I2C* Interfaces		49
	3.12. Network Status Indication		50
	3.13. STATUS		52



	3.14. Behaviors of RI		52
	3.15. USB_BOOT Interface		53
	3.16. ADC Interfaces		54
	3.17. GPIOInterfaces		55
4			
	'		
	4.3. Layout Guidelines		58
5			
		RF Antenna Interface	
		RF Layout	
	•	S	
	5.3.2. Recommended RF Co	onnector for Antenna Installation	66
6		haracteristics	
	· ·		
		eratures	
	•		
	•		
	6.7. Electrostatic Discharge		78
7			
		e Module	
	·		
	7.3. Design Effect Drawings of the	e Module	82
8		aging	
	•		
		J	
	8.3. Packaging		86
9	Appendix A References		88
10	Appendix B GPRS Coding Schem	nes	91
11	Appendix C GPRS Multi-slot Class	ses	92
12	Appendix D EDGE Modulationand	d Coding Schemes	94



## **Table Index**

TABLE 1: FREQUENCY BANDS OF BG96 MODULE	14
TABLE 2: KEY FEATURES OF BG96 MODULE	15
TABLE 3: DEFINITION OF I/O PARAMETERS	23
TABLE 4: PIN DESCRIPTION	23
TABLE 5: OVERVIEW OF OPERATING MODES	30
TABLE 6: VBAT AND GND PINS	35
TABLE 7: PIN DEFINITION OF PWRKEY	37
TABLE 8: RESET_N PIN DESCRIPTION	40
TABLE 9: PIN DEFINITION OF (U)SIM INTERFACE	42
TABLE 10: PIN DEFINITION OF USB INTERFACE	45
TABLE 11: PIN DEFINITION OF UART1 INTERFACE	47
TABLE 12: PIN DEFINITION OF UART2 INTERFACE	47
TABLE 13: PIN DEFINITION OF UART3 INTERFACE	47
TABLE 14:LOGIC LEVELS OF DIGITAL I/O	48
TABLE 15: PIN DEFINITION OF PCM AND I2C INTERFACES	49
TABLE 16: PIN DEFINITION OF NETLIGHT	51
TABLE 17: WORKING STATE OF NETLIGHT	
TABLE 18: PIN DEFINITION OF STATUS	52
TABLE 19: DEFAULT BEHAVIORS OF RI	53
TABLE 20: PIN DEFINITION OF USB_BOOT INTERFACE	54
TABLE 21: PIN DEFINITION OF ADC INTERFACES	55
TABLE 22: CHARACTERISTICS OF ADC INTERFACES	55
TABLE 23: PIN DEFINITION OF GPIO INTERFACES	56
TABLE 24:LOGIC LEVELS OF GPIO INTERFACES	
TABLE 25: GNSS PERFORMANCE	
TABLE 26: PIN DEFINITION OF MAIN ANTENNA INTERFACE	59
TABLE 27: BG96 OPERATING FREQUENCY	59
TABLE 28: PIN DEFINITION OF GNSS ANTENNA INTERFACE	64
TABLE 29: GNSS FREQUENCY	64
TABLE 30: ANTENNA REQUIREMENTS	66
TABLE 31: ABSOLUTE MAXIMUM RATINGS	69
TABLE 32: POWER SUPPLY RATINGS	70
TABLE 33: OPERATION AND STORAGE TEMPERATURES	70
TABLE 34: BG96 CURRENT CONSUMPTION	71
TABLE 35: GNSS CURRENT CONSUMPTION	75
TABLE 36: RF OUTPUT POWER	75
TABLE 37: BG96 CONDUCTED RF RECEIVING SENSITIVITY	76
TABLE 38: ELECTROSTATIC DISCHARGE CHARACTERISTICS	78
TABLE 39: RECOMMENDED THERMAL PROFILE PARAMETERS	
TABLE 40: REEL PACKAGING	87
TABLE 41: RELATED DOCUMENTS	88





TABLE 42: TERMS AND ABBREVIATIONS	88
TABLE 43: DESCRIPTION OF DIFFERENT CODING SCHEMES	91
TABLE 44: GPRS MULTI-SLOT CLASSES	92
TABLE 45: EDGE MODUL ATION AND CODING SCHEMES	Q4



## Figure Index

FIGURE 1: FUNCTIONAL DIAGRAM	18
FIGURE 2: PIN ASSIGNMENT (TOP VIEW)	22
FIGURE 3: SLEEP MODE APPLICATION VIA UART	34
FIGURE 4: POWER SUPPLY LIMITS DURING BURST TRANSMISSION	36
FIGURE 5: STAR STRUCTURE OF THE POWER SUPPLY	37
FIGURE 6: TURN ON THE MODULE USING DRIVING CIRCUIT	38
FIGURE 7: TURN ON THE MODULE USING KEYSTROKE	38
FIGURE 8: TIMING OF TURNING ON MODULE	39
FIGURE 9: TIMING OF TURNING OFF MODULE	40
FIGURE 10: REFERENCE CIRCUIT OF RESET_N BY USING DRIVING CIRCUIT	41
FIGURE 11: REFERENCE CIRCUIT OF RESET_N BY USING BUTTON	41
FIGURE 12: TIMING OF RESETTING MODULE	42
FIGURE 13: REFERENCE CIRCUIT OF (U)SIM INTERFACE WITH AN 8-PIN (U)SIM CARD CONNECT	OR
FIGURE 14: REFERENCE CIRCUIT OF (U)SIM INTERFACE WITH A 6-PIN (U)SIM CARD CONNECTO	R. 44
FIGURE 15: REFERENCE CIRCUIT OF USB INTERFACE	45
FIGURE 16: REFERENCE CIRCUIT WITH TRANSLATOR CHIP	48
FIGURE 17: REFERENCE CIRCUIT WITH TRANSISTOR CIRCUIT	49
FIGURE 18: REFERENCE CIRCUIT OF PCM APPLICATION WITH AUDIO CODEC	50
FIGURE 19: REFERENCE CIRCUIT OF THE NETWORK STATUS INDICATOR	51
FIGURE 20: REFERENCE CIRCUIT OF STATUS	52
FIGURE 21: REFERENCE CIRCUIT OF USB_BOOT INTERFACE	54
FIGURE 22: REFERENCE CIRCUIT OF RF ANTENNA INTERFACE	61
FIGURE 23: MICROSTRIP LINE DESIGN ON A 2-LAYER PCB	62
FIGURE 24: COPLANAR WAVEGUIDE LINE DESIGN ON A 2-LAYER PCB	62
FIGURE 25: COPLANAR WAVEGUIDE LINE DESIGN ON A 4-LAYER PCB (LAYER 3 AS REFERENCE	
GROUND)	63
FIGURE 26: COPLANAR WAVEGUIDE LINE DESIGN ON A 4-LAYER PCB (LAYER 4 AS REFERENCE	
GROUND)	
FIGURE 27: REFERENCE CIRCUIT OF GNSS ANTENNA INTERFACE	
FIGURE 28: DIMENSIONS OF THE U.FL-R-SMT CONNECTOR (UNIT: MM)	67
FIGURE 29: MECHANICALS OF U.FL-LP CONNECTORS	
FIGURE 30: SPACE FACTOR OF MATED CONNECTOR (UNIT: MM)	
FIGURE 31: MODULE TOP AND SIDE DIMENSIONS	
FIGURE 32: MODULE BOTTOM DIMENSIONS (BOTTOM VIEW)	80
FIGURE 33: RECOMMENDED FOOTPRINT (TOP VIEW)	81
FIGURE 34: TOP VIEW OF THE MODULE	
FIGURE 35: BOTTOM VIEW OF THE MODULE	
FIGURE 36: RECOMMENDED REFLOW SOLDERING THERMAL PROFILE	
FIGURE 37: TAPE DIMENSIONS	
FIGURE 38: REEL DIMENSIONS	87



 $\mathbf 1$  Introduction

This document defines BG96module and describes its air interface and hardware interfaces which are

connected with customers' applications.

This document can help customers quickly understand the interface

specifications, electrical and mechanical details, as well as other related

information of BG96. To facilitate its application in different fields, reference

design is also provided for customers' reference. Associated with application

notes and user guides, customers can use the module to design and set up

mobile applications easily.

Model: BG96, BG96 MINIPCIE

FCC ID: XMR201707BG96

IC: 10224A-201709BG96

Model: BG96-M

FCC ID: XMR201901BG96M



## 1.1. Safety Information

The following safety precautions must be observed during all phases of the operation, such as usage, service or repair of any cellular terminal or mobile incorporating BG96. Manufacturers of the cellular terminal should send the following safety information to users and operating personnel, and incorporate these guidelines into all manuals supplied with the product. If not so, Quectel assumes no liability for customers' failure to comply with these precautions.



Full attention must be given to driving at all times in order to reduce the risk of an accident. Using a mobile while driving (even with a handsfree kit) causes distraction and can lead to an accident. Please comply with laws and regulations restricting the use of wireless devices while driving.



Switch off the cellular terminal or mobile before boarding an aircraft. The operation of wireless appliances in an aircraft is forbidden to prevent interference with communication systems. If the device offers an Airplane Mode, then it should be enabled prior to boarding an aircraft. Please consult the airline staff for more restrictions on the use of wireless devices on boarding the aircraft.



Wireless devices may cause interference on sensitive medical equipment, so please be aware of the restrictions on the use of wireless devices when in hospitals, clinics or other healthcare facilities.



Cellular terminals or mobiles operating over radio signals and cellular network cannot be guaranteed to connect in all possible conditions (for example, with unpaid bills or with an invalid (U)SIM card). When emergent help is needed in such conditions, please remember using emergency call. In order to make or receive a call, the cellular terminal or mobile must be switched on in a service area with adequate cellular signal strength.



The cellular terminal or mobile contains a transmitter and receiver. When it is ON, it receives and transmits radio frequency signals. RF interference can occur if it is used close to TV set, radio, computer or other electric equipment.





In locations with potentially explosive atmospheres, obey all posted signs to turn off wireless devices such as your phone or other cellular terminals. Areas with potentially explosive atmospheres include fuelling areas, below decks on boats, fuel or chemical transfer or storage facilities, areas where the air contains chemicals or particles such as grain, dust or metal powders, etc.



## 1.2. FCC/ISED Regulatory notices

#### **Modification statement**

Quectel has not approved any changes or modifications to this device by the user. Any changes or modifications could void the user's authority to operate the equipment.

Quectel n'approuve aucune modification apportée à l'appareil par l'utilisateur, quelle qu'en soit la nature. Tout changement ou modification peuvent annuler le droit d'utilisation de l'appareil par l'utilisateur.

#### **Interference statement**

This device complies with Part 15 of the FCC Rules and Industry Canada licence-exempt RSS standard(s). Operation is subject to the following two conditions: (1) this device may not cause interference, and (2) this device must accept any interference, including interference that may cause undesired operation of the device.

Le présent appareil est conforme aux CNR d'Industrie Canada applicables aux appareils radio exempts de licence. L'exploitation est autorisée aux deux conditions suivantes : (1) l'appareil ne doit pas produire de brouillage, et (2) l'utilisateur de l'appareil doit accepter tout brouillage radioélectrique subi, même si le brouillage est susceptible d'en compromettre le fonctionnement.

#### RF exposure

This equipment complies with FCC and ISED radiation exposure limits set forth for an uncontrolled environment. The antenna should be installed and operated with minimum distance of 20 cm between the radiator and your body. Antenna gain must be below:

#### **Antenna Gain**

Frequency Band	FCC ID: XMR201901BG96M	FCC ID: XMR201707BG96
	Model: BG96-M	Model: BG96, BG96 MINIPCIE
GSM850	NA	10.446dBi
GSM1900	NA	12.030dBi
LTE band2	8dBi	9.0dBi
LTE band4	5dBi	7.0dBi
LTE band5	9.42dBi	10.416dBi
LTE band12	8.73dBi	9.734dBi
LTE band13	9.17dBi	10.173dBi
LTE band25	8dBi	8.0dBi

This transmitter must not be co-located or operating in conjunction with any other antenna or transmitter.

Cet appareil est conforme aux limites d'exposition aux rayonnements de l'ISED pour un environnement non contrôlé. L'antenne doit être installé de façon à garder une distance minimale de 20 centimètres entre la source de rayonnements et votre corps. Gain de l'antenne doit être ci-dessous:

#### Gain de l'antenne

**□** GSM850:≤7.13dBi

■ GSM1900:≤12.03dBi

□ LTE Band2:≤9.0dBi

□ LTE Band4:≤7.0dBi



□ LTE Band5:≤7.1dBi

□ LTE Band12:≤6.61dBi

□ LTE Band13:≤6.93dBi

□ LTE Band25:≤8.0dBi

L'émetteur ne doit pas être colocalisé ni fonctionner conjointement avec à autre antenne ou autre émetteur.

#### FCC Class B digital device notice

This equipment has been tested and found to comply with the limits for a Class B digital device, pursuant to part 15 of the FCC Rules. These limits are designed to provide reasonable protection against harmful interference in a residential installation. This equipment generates, uses and can radiate radio frequency energy and, if not installed and used in accordance with the instructions, may cause harmful interference to radio communications. However, there is no guarantee that interference will not occur in a particular installation. If this equipment does cause harmful interference to radio or television reception, which can be determined by turning the equipment off and on, the user is encouraged to try to correct the interference by one or more of the following measures:

- Reorient or relocate the receiving antenna.
- Increase the separation between the equipment and receiver.
- Connect the equipment into an outlet on a circuit different from that to which the receiver is connected.
- Consult the dealer or an experienced radio/TV technician for help.

#### Labelling Requirements for the Host device

The host device shall be properly labelled to identify the modules within the host device. The certification label of the module shall be clearly visible at all times when installed in the host device, otherwise the host device must be labelled to display the FCC ID and ISED of the module, preceded by the words "Contains transmitter module", or the word "Contains", or similar wording expressing the same meaning, as follows:

#### Model: BG96, BG96 MINIPCIE

Contains FCC ID: XMR201707BG96 Contains IC: 10224A-201709BG96

Model: BG96-M

Contains FCC ID: XMR201901BG96M

L'appareil hôte doit être étiqueté comme il faut pour permettre l'identification des modules qui s'y trouvent. L'étiquette de certification du module donné doit être posée sur l'appareil hôte à un endroit bien en vue en tout temps. En l'absence d'étiquette, l'appareil hôte doit porter une étiquette donnant le FCC ID et l'ISED du module, précédé des mots « Contient un module d'émission », du mot « Contient » ou d'une formulation similaire exprimant le même sens, comme suit :

## Model: BG96, BG96 MINIPCIE

Contient FCC ID: XMR201707BG96 Contient IC: 10224A-201709BG96

#### CAN ICES-3 (B) / NMB-3 (B)

This Class B digital apparatus complies with Canadian ICES-003.

Cet appareil numérique de classe B est conforme à la norme canadienne ICES-003.



# **2** Product Concept

## 2.1. General Description

BG96isa series ofembeddedIoT(LTE Cat.M1/LTE Cat.NB1/EGPRS) wireless communication module.It provides data connectivity on LTE-TDD/LTE-FDD/GPRS/EGPRSnetworks, and supports half-duplex operation in LTE networks. It also provides GNSS<sup>1)</sup>and voice<sup>2)</sup>functionalityto meet customers'specific application demands.BG96 contains two variants: BG96 and BG96-M. Customers can choose a dedicated type based on the region or operator. The following table shows the frequency bands of BG96 modules.

**Table 1: Frequency Bands of BG96 Modules** 

Module	LTE Bands	GSM <sup>3)</sup>	Rx-diversity	GNSS <sup>1)</sup>
BG96	Cat M1& NB1: LTE-FDD: B1/B2/B3/B4/B5/B8/B12/ B13/B18/B19/B20/B25 <sup>4</sup> )/ B26 <sup>5</sup> )/B28 LTE-TDD: B39 (for Cat M1 only)	GSM850/EGSM900/ DCS1800/PCS1900	Not Supported	GPS, GLONASS,BeiDo u/Compass, Galileo, QZSS
BG96-M	Cat M1 only: LTE-FDD: B1/B2/B3/B4/B5/B8/B12/ B13/B18/B19/B20/B25 <sup>4)</sup> / B26 <sup>5)</sup> /B28 LTE-TDD: B39 (for Cat M1 only)	Not Supported	Not Supported	GPS, GLONASS,BeiDo u/Compass, Galileo, QZSS





- 1. 1) GNSS function is optional.
- 2. <sup>2)</sup> BG96 supports VoLTE(Voice over LTE) under LTECat M1 network.
- 3. <sup>3)</sup>BG96 GSM only supports Packet Switch.
- 4. <sup>4)</sup>B25 will be supported on BG96 modules with R1.2 hardware version.
- 5. <sup>5)</sup>B26 is under development.

With a compact profile of 26.5mm ×22.5mm ×2.3mm, BG96 can meet almost all requirements for M2M applications such as smart metering, tracking system, security, wireless POS, etc.

BG96 is an SMD type module which can be embedded into applications through its 102 LGA pads.BG96supports internet service protocols like TCP, UDP and PPP. Extended AT commands have been developed for customers to use these internet service protocols easily.

## 2.2. Key Features

The following table describes the detailed features of BG96 modules.

**Table 2: Key Features of BG96Modules** 

Features	Details
Power Supply	Supply voltage: 3.3V~4.3V
Fower Suppry	Typical supply voltage: 3.8V
	Class 3 (23dBm±2dB) for LTE-FDD bands
	Class 3 (23dBm±2dB) for LTE-TDD bands
	Class 4 (33dBm±2dB) for GSM850
	Class 4 (33dBm±2dB) for EGSM900
Transmitting Power	Class 1 (30dBm±2dB) for DCS1800
Transmitting Fower	Class 1 (30dBm±2dB) for PCS1900
	Class E2 (27dBm±3dB) for GSM850 8-PSK
	Class E2 (27dBm±3dB) for EGSM900 8-PSK
	Class E2 (26dBm±3dB) for DCS1800 8-PSK
	Class E2 (26dBm±3dB) for PCS1900 8-PSK
	Support LTE Cat M1 and LTE Cat NB1
LTE Features	Support 1.4MHz RF bandwidth for LTE Cat M1
LILI Galuies	Support 200KHz RF bandwidth for LTE Cat NB1
	Support SISO in DL direction



	Cat M1: Max. 375Kbps (DL)/375Kbps (UL) Cat NB1: Max. 32Kbps (DL)/70Kbps (UL)
GSMFeatures	GPRS: Support GPRS multi-slot class 33 (33 by default) Coding scheme: CS-1, CS-2, CS-3 and CS-4 Max. 107Kbps (DL), Max. 85.6Kbps (UL) EDGE: Support EDGE multi-slot class 33 (33 by default) Support GMSK and 8-PSK for different MCS (Modulation and Coding Scheme) Downlink coding schemes: CS 1-4 and MCS 1-9 Uplink coding schemes: CS 1-4 and MCS 1-9 Max. 296Kbps (DL), Max. 236.8Kbps (UL)
Internet Protocol Features	Support PPP/TCP/UDP/SSL/TLS/FTP(S)/HTTP(S)/NITZ/PING/MQTTprotocols Support PAP (Password Authentication Protocol) and CHAP (Challenge Handshake Authentication Protocol) protocols which are usually used for PPP connections
SMS	Text and PDU mode Point to point MO and MT SMS cell broadcast SMS storage: ME by default
(U)SIM Interface	Support USIM/SIM card: 1.8V, 3.0V
Audio Feature*	Support one digital audio interface: PCM interface
USB Interface	Compliant with USB 2.0 specification (slave only) and the data transfer rate can reach up to 480Mbps  Used for AT command communication, data transmission, GNSS NMEA output, software debugging and firmware upgrade  SupportUSB serial drivers forWindows 7/8/8.1/10, Windows CE 5.0/6.0/7.0, Linux 3.x(3.4 or later)/4.1~4.14, Android 4.x/5.x/6.x/7.x/8.x.
UART Interfaces	<ul> <li>UART1:</li> <li>Used for data transmission and AT command communication</li> <li>115200bps by default</li> <li>The default frame format is 8N1 (8 data bits, no parity, 1 stop bit)</li> <li>Support RTS and CTS hardware flow control</li> <li>UART2:</li> <li>Used for module debugging and log output</li> <li>115200bps baud rate</li> <li>UART3:</li> <li>Used for outputting GNSS data or NMEA sentences</li> <li>115200bps baud rate</li> </ul>
AT Commands	3GPP TS 27.007 and 3GPP TS 27.005 AT commands, as well as Quectel enhanced AT commands



Network Indication	OneNETLIGHT pin for network connectivity status indication
Antenna Interfaces	Including main antenna (ANT_MAIN) and GNSS antenna (ANT_GNSS) interfaces
Physical Characteristics	Size: $(26.5\pm0.15)$ mm× $(22.5\pm0.15)$ mm × $(2.3\pm0.2)$ mm Weight: approx. 3.1g
Temperature Range	Operation temperature range: -35°C ~ +75°C <sup>1)</sup> Extended temperature range: -40°C ~ +85°C <sup>2)</sup> Storage temperature range: -40°C ~ +90°C
Firmware Upgrade	USB interface, DFOTA
RoHS	All hardware components are fully compliant with EU RoHS directive

#### **NOTES**

- 1. "\*" means under development.
- 2. 1) Within operation temperature range, the module is 3GPP compliant.
- 3. <sup>2)</sup> Within extended temperature range, the module remains the ability to establish and maintain a voice, SMS, data transmission, emergency call, etc. There is no unrecoverable malfunction. There are also no effects on radio spectrum and no harm to radio network. Only one or more parameters like P<sub>out</sub> might reduce in their value and exceed the specified tolerances. When the temperature returns to the normal operating temperature levels, the module will meet 3GPP specificationsagain.

## 2.3. Functional Diagram

The following figure shows a block diagram of BG96 and illustrates the major functional parts.

- Power management
- Baseband
- DDR+NAND flash
- Radio frequency
- Peripheral interfaces



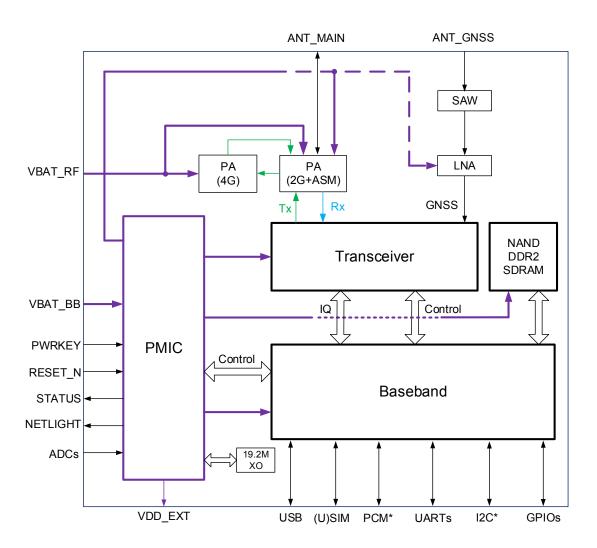


Figure 1: Functional Diagram

NOTE

"\*" means under development.

## 2.4. Evaluation Board

In order to help customers develop applications conveniently with BG96, Quectel supplies the evaluation board (EVB), USB to RS-232converter cable, USB data cable, earphone, antenna and other peripherals to control or test the module. For more details, please refer to **document [1]**.





# **3** Application Interfaces

BG96is equipped with 102 LGA pads that can be connected to customers' cellular application platforms. The following sub-chapters will provide detailed description of interfaces listed below:

- Power supply
- (U)SIMinterface
- USB interface
- UART interfaces
- PCM\* and I2C\* interfaces
- Status indication
- USB\_BOOT interface
- ADC interfaces
- GPIO interfaces

#### **NOTE**

"\*" means under development.



## 3.1. Pin Assignment

The following figure showsthe pin assignment of BG96.



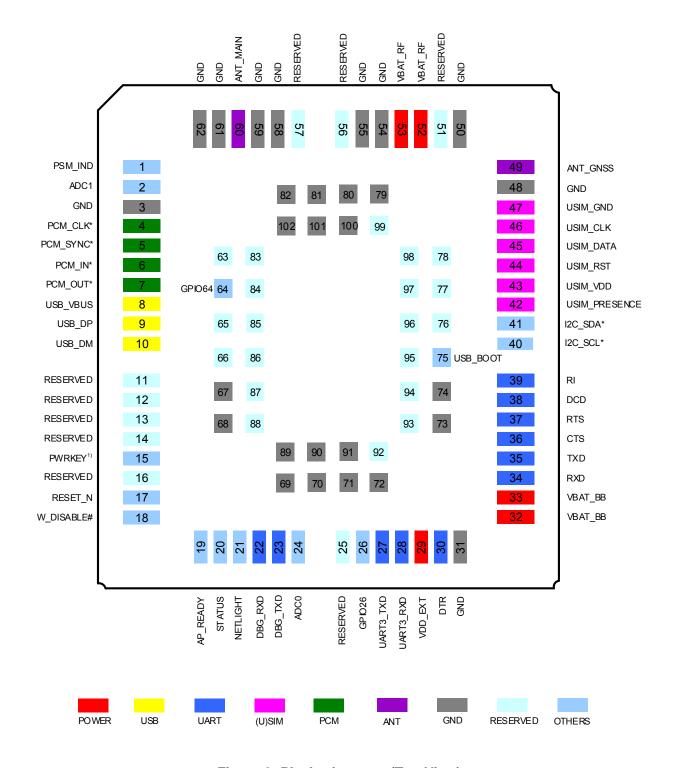


Figure 2: Pin Assignment (Top View)

#### **NOTES**

- 1. Keep all RESERVEDpins and unused pins unconnected.
- 2. GND pads should be connected to ground in the design.



- 3. 1)PWRKEY output voltage is 0.8V because of the diode drop in the Qualcomm chipset.
- 4. "\*" means under development.

## 3.2. Pin Description

The following tables show the pin definition and description of BG96.

Table 3: Definition of I/O Parameters

Туре	Description
Ю	Bidirectional
DI	Digital input
DO	Digital output
PI	Power input
РО	Power output
Al	Analog input
AO	Analog output
OD	Open drain

**Table 4: Pin Description** 

Power Supply	у				
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment
VBAT_BB	32, 33	PI	Power supply for the module's baseband part	Vmax=4.3V Vmin=3.3V Vnorm=3.8V	
VBAT_RF	52,53	PI	Power supply for the	Vmax=4.3V Vmin=3.3V	



		module's RF	Vnorm=3.8V	
		part		
29	РО	Provide 1.8V for external circuit	Vnorm=1.8V I <sub>O</sub> max=50mA	Power supply for externa GPIO's pull-up circuits.
3, 31, 48, 50, 54, 55, 58, 59, 61, 62, 67~74, 79~82, 89~91, 100~102		Ground		
Pin No.	I/O	Description	DC Characteristics	Comment
15	DI	Turnon/off the module	<mark>Vnorm=0.8V</mark> V <sub>IL</sub> max=0.5V	The output voltage is 0.8V because of the diode drop in the Qualcomm chipset.
17	DI	Resetthe module	V <sub>IH</sub> max=2.1V V <sub>IH</sub> min=1.3V V <sub>IL</sub> max=0.5V	If unused, keep this pin open.
on				
Pin No.	I/O	Description	DC Characteristics	Comment
20	DO	Indicate the module'soperat ionstatus	V <sub>OH</sub> min=1.35V V <sub>OL</sub> max=0.45V	1.8V power domain. If unused, keep this pin open.
21	DO	Indicate the module'snetwor k activity status	V <sub>OH</sub> min=1.35V V <sub>OL</sub> max=0.45V	1.8V power domain. If unused, keep this pin open.
Pin No.	I/O	Description	DC Characteristics	Comment
			Vmax=5.25V	
8	PI	USB detection	Vmin=3.0V	
9	Ю	USB differential data bus(+)	Compliant with USB 2.0 standard specification.	Require differential impedance of $90\Omega$ .
	3, 31, 48, 50, 54, 55, 58, 59, 61, 62, 67~74, 79~82, 89~91, 100~102  Pin No.  15  17  Pin No.  20  21  Pin No.	3, 31, 48, 50, 54, 55, 58, 59, 61, 62, 67~74, 79~82, 89~91, 100~102  Pin No. I/O  15 DI  17 DI  on Pin No. I/O  20 DO  21 DO  Pin No. I/O  8 PI	29 PO for external circuit  3, 31, 48, 50, 54, 55, 58, 59, 61, 62, 67~74, 79~82, 89~91, 100~102  Pin No. I/O Description  15 DI Resetthe module  17 DI Resetthe module  18 DO Description  Indicate the module'soperat ionstatus Indicate the module'snetwor k activity status  Pin No. I/O Description  Pin No. I/O Description  USB differential	29



USB_DM	10	Ю	USB differential data bus (-)	Compliant with USB 2.0 standard specification.	Require differential impedance of $90\Omega$ .			
(U)SIM Interface								
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment			
USIM_ PRESENCE	42	DI	(U)SIM card insertion detection	V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. If unused, keep this pin open.			
LISIM VDD	42	DO	Power supply	For 1.8V(U)SIM: Vmax=1.9V Vmin=1.7V	Either 1.8V or 3.0V is			
USIM_VDD	)() 43 P()	for (U)SIM card	For 3.0V(U)SIM: Vmax=3.05V Vmin=2.7V I <sub>O</sub> max=50mA	supported by the module automatically.				
USIM_RST	44 D	DO	Reset signal of	For 1.8V (U)SIM: V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V				
			(U)SIM card	For 3.0V (U)SIM: $V_{OL}$ max=0.45V $V_{OH}$ min=2.55V				
USIM_DATA	45	Dat 45 IO	Data signal of (U)SIM card	For 1.8V (U)SIM: $V_{IL}$ max=0.6V $V_{IH}$ min=1.2V $V_{OL}$ max=0.45V $V_{OH}$ min=1.35V				
				For 3.0V (U)SIM: $V_{IL}$ max=1.0V $V_{IH}$ min=1.95V $V_{OL}$ max=0.45V $V_{OH}$ min=2.55V				
IISIM CI K	46	DO	Clock signal of	For 1.8V (U)SIM: V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V				
USIM_CLK	46 DO	(U)SIM card	For 3.0V (U)SIM: V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=2.55V					



USIM_GND	47		Specified ground for (U)SIM card		
UART1 Interfac	ce				
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment
DTR	30	DI	Data terminal ready(sleepmo de control)	$V_{IL}$ min=-0.3V $V_{IL}$ max=0.6V $V_{IH}$ min=1.2V $V_{IH}$ max=2.0V	1.8V power domain. If unused, keep this pin open.
RXD	34	DI	Receive data	$V_{IL}$ min=-0.3V $V_{IL}$ max=0.6V $V_{IH}$ min=1.2V $V_{IH}$ max=2.0V	1.8V power domain. If unused, keep this pin open.
TXD	35	DO	Transmit data	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.
CTS	36	DO	Clear to send	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.
RTS	37	DI	Request to send	V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. If unused, keep this pin open.
DCD	38	DO	Data carrier detection	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.
RI	39	DO	Ring indicator	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.
UART2 Interfac	ce				
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment
DBG_RXD	22	DI	Receive data	V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. If unused, keep this pin open.
DBG_TXD	23	DO	Transmit data	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.
UART3 Interfac	ce				



Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment		
UART3_TXD	27	DO	Transmit data	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.		
UART3_RXD	28	DI	Receive data	V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. If unused, keep this pin open.		
PCM* Interface	Э						
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment		
PCM_CLK*	4	DO	PCMclock output	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.		
PCM_SYNC*	5	DO	PCMframe synchronization output	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.		
PCM_IN*	6	DI	PCMdata input	V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. If unused, keep this pin open.		
PCM_OUT*	7	DO	PCMdata output	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.		
I2C* Interface							
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment		
					External pull-up resistor is required.		
I2C_SCL*	40	OD	I2C serial clock. Used for external codec.		1.8V only.  If unused, keep		
					this pin open.		
I2C_SDA*	41	OD	I2C serial data. Used for external codec.		External pull-up resistor is required. 1.8V only. If unused, keep this pin open.		



Antenna Interfa	aces				
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment
ANT_MAIN	60	Ю	Main antenna interface	50Ωimpedance	
ANT_GNSS	49	AI	GNSS antenna interface	50Ωimpedance	If unused, keep this pin open.
Other Pins					
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment
PSM_IND <sup>1)</sup>	1	DO	Power saving mode indicator	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V	1.8V power domain. If unused, keep this pin open.
W_DISABLE#	18	DI	Airplane mode control	V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. Pull-up by default. In low voltage level, the module can enter into airplane mode. If unused, keep this pin open.
AP_READY	19	DI	Application processor sleep state detection	V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. If unused, keep this pin open.
USB_BOOT	75	DI	Force the module to enter into emergency download mode	V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. If unused, keep this pin open.
GPIO26	26	Ю	General- purpose input/ output interface	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. If unused, keep this pin open.
GPIO64	64	Ю	General- purpose input/ output interface	V <sub>OL</sub> max=0.45V V <sub>OH</sub> min=1.35V V <sub>IL</sub> min=-0.3V V <sub>IL</sub> max=0.6V V <sub>IH</sub> min=1.2V V <sub>IH</sub> max=2.0V	1.8V power domain. If unused, keep this pin open.



ADC Interfaces						
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment	
ADC1	2	Al	General purpose analog to digital converter interface	Voltage range: 0.3V to 1.8V	If unused, keep this pin open.	
ADC0	24	Al	General purpose analog to digital converter interface	Voltage range: 0.3V to 1.8V	If unused, keep this pin open.	
RESERVED P	ns					
Pin Name	Pin No.	I/O	Description	DC Characteristics	Comment	
RESERVED	11~14, 16, 25, 51, 56, 57, 63, 65,66, 76~78, 83~88,		Reserved		Keep these pins open.	

### **NOTES**

- 1. "\*" means under development.
- 2. <sup>1)</sup> When PSM is enabled and then reboot the module, the function of PSM\_IND pin will be activated. This pin outputs a high level voltage when the module is in normal operation state, and outputs a low level voltage when the module enters into PSM.
- 3. Keep all RESERVED pins and unused pins unconnected.



## 3.3. Operating Modes

The table below briefly summarizes the various operating modes referred in the following chapters.

**Table 5: Overview of Operating Modes** 

Mode	Details						
Normal	Talk/Data	Network connection is ongoing. In this mode, the power consumption is decided by network settingand data transfer rate.					
Operation	Idle	Software is active. The module hasregistered onnetwork, and it is ready to send and receive data.					
Extended Idle Mode DRX (e-I-DRX)	use of e-I-DR terminating dat	BG96 module and the network may negotiate over non-access stratum signaling the use of e-I-DRX for reducing power consumption, while being available for mobile terminating data and/or network originated procedures within a certain delay dependent on the DRX cycle value.					
Airplane Mode	<b>AT+CFUN</b> command or W_DISABLE# pin can set the module into airplane mode. In this case, RF function will be invalid.						
Minimum Functionality Mode	<b>AT+CFUN</b> command can set the module into a minimum functionality mode without removing the power supply. In this case, both RF function and (U)SIM card will be invalid.						
Sleep Mode	In this mode, the current consumption of the module will be reduced to a lower level. During this mode, the module can still receive paging message, SMS and TCP/UDP data from the network normally.						
	BG96 mod	ule may enter into Power Saving Mode for reducing its					
Power Saving Mode	power consumption. PSM is similar to power-off, but the mod						
(PSM)	remains re	remains registered on the network and there is no need to					
	re-attach o	r re-establish PDN connections.					
Power OFF Mode	active. The se	ne power management unit shuts down the power supply. Software is not erial interfacesare not accessible. Butoperating voltage (connected to VBAT_BB) remains applied.					





During e-I-DRX, it is recommended to use UART interface for data communication, as the use of USB interface will increase power consumption.

## 3.4. Power Saving

#### 3.4.1. Airplane Mode

When the module enters into airplane mode, the RF function does not work, and all AT commands correlative with RF function will be inaccessible. This mode can be set via the following ways.

#### Hardware:

W\_DISABLE# is pulled up by default.Driving it to low level will let the module enter into airplane mode.

#### Software:

**AT+CFUN=<fun>**command provides choice of the functionality level, through setting **<fun>** into 0, 1 or 4.

• AT+CFUN=0: Minimum functionality mode. Both (U)SIM and RF functions are disabled.

**AT+CFUN=1**: Full functionality mode (by default).

**AT+CFUN=4**: Airplane mode. RF function is disabled.

#### **NOTES**

- 1. Airplane mode control viaW\_DISABLE# is disabled in firmware by default. It can be enabled by AT+QCFG="airplanecontrol" command.
- 2. The execution of AT+CFUN command will not affect GNSS function.

#### 3.4.2. Power Saving Mode(PSM)

BG96 module can enter into PSM for reducing its power consumption. The



mode is similar to power-off, but the module remains registered on the network and there is no need to re-attach or re-establish PDN connections. So BG96 in PSM cannot immediately respond users' requests.

When the module wants to use the PSM it shall request an Active Time value during every Attach and TAU procedures. If the network supports PSM and accepts that the module uses PSM, the network confirms usage of PSM by allocating an Active Time value to the module. If the module wants to change the Active Time value, e.g. when the conditions are changed in the module, the module consequently requests the value it wants in the TAU procedure.

If PSM is supported by the network, then it can be enabled via **AT+CPSMS**command.

Either of the following methods will wake up the module from PSM:

- Drive PWRKEY pin to low level will wake up the module.
- When the T3412 Exttimer expires, the module will be automatically woken up.

**NOTE** 

Please refer to document [2] for details about AT+CPSMScommand.

#### 3.4.3. Extended Idle Mode DRX(e-I-DRX)

The module (UE) and the network may negotiate over non-access stratum signalling the use of e-I-DRX for reducing its power consumption, while being available for mobile terminating data and/or network originated procedures



within a certain delay dependent on the DRX cycle value.

Applications that want to use e-I-DRX need to consider specific handling of mobile terminating services or data transfers, and in particular they need to consider the delay tolerance of mobile terminated data.

In order to negotiate the use of e-I-DRX, the UE requests e-I-DRXparameters during attach procedure and RAU/TAU procedure. The EPC may reject or accept the UE request for enabling e-I-DRX. In case the EPC accepts e-I-DRX, the EPC based on operator policies and, if available, the e-I-DRXcycle length value in the subscription data from the HSS, may also provide different values of the e-I-DRXparameters than what was requested by the UE. If the EPC accepts the use of e-I-DRX, the UE applies e-I-DRX based on the received e-I-DRXparameters. If the UE does not receive e-I-DRXparameters in the relevant accept message because the EPC rejected its request or because the request was received by EPC not supporting e-I-DRX, the UE shall apply its regular discontinuous reception.

Ife-I-DRX is supported by the network, then it can be enabled by AT+CEDRXS=1command.

NOTE



Please refer to document [2] for details about AT+CEDRXScommand.

#### 3.4.4. Sleep Mode

BG96 is able to reduce its current consumption to a lower value during the sleep mode. The following sub-chapters describe the power saving procedure of BG96 module.

#### 3.4.4.1. UART Application

If the host communicates with module via UART interface, the following preconditions can let the module enter into sleep mode.

- Execute AT+QSCLK=1command to enable sleep mode.
- Drive DTR to high level.

The following figure shows the connection between the module and the host.

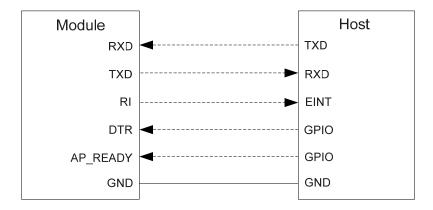


Figure 3: Sleep Mode Application via UART

Driving the host DTR to low level will wake up the module.

- When BG96 has URC to report, RI signal will wake up the host. Please refer to Chapter 3.14 for details about RI behavior.
- AP\_READY will detect the sleep state of the host (can be configured to high level or low level detection). Please refer to AT+QCFG="apready" command in document [2] for details.



## 3.5. Power Supply

#### 3.5.1. Power Supply Pins

BG96 provides the following four VBAT pins for connection with anexternal power supply. There are two separate voltage domains for VBAT.

- Two VBAT\_RF pins for module'sRF part.
- Two VBAT\_BB pins for module's baseband part.

The following table shows the details of VBAT pins and ground pins.

**Table 6: VBAT and GND Pins** 

Pin Name	Pin No.	Description	Min.	Тур.	Max.	Unit
VBAT_RF	52,53	Power supply for the module's RF part	3.3	3.8	4.3	V
VBAT_BB	32,33	Power supply for the module's baseband part	3.3	3.8	4.3	V
GND	3, 31, 48,50, 54, 55,58, 59, 61,62, 67~74, 79~82,89~91,100 ~102	Ground	-	-	-	-

#### 3.5.2. Decrease Voltage Drop

The power supply range of the module is from 3.3Vto4.3V. Please make sure that the input voltage will never drop below 3.3V.The following figure shows the voltage drop during burst transmission in 2G network. The voltage drop will be less in LTE CatM1 and LTE CatNB1 networks.



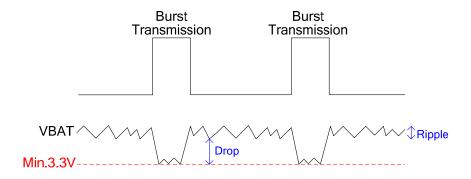


Figure 4: Power Supply Limits during Burst Transmission

To decrease voltage drop, a bypass capacitor of about 100µF with low ESRshould be used, and a multi-layer ceramic chip capacitor (MLCC) array should also be reserved due to its low ESR.It is recommended to use three ceramic capacitors (100nF, 33pF, 10pF) for composing the MLCC array, and place these capacitors close to VBAT pins.The main power supply from an external application has to be a single voltage source and can be expanded to two sub paths with star structure. The width of VBAT\_BB trace should be no less than 0.5mm, and the width of VBAT\_RF trace should be no less than 2mm. In principle, the longer the VBAT trace is, the wider it will be.

In addition, in order to get a stable power source, it is suggested to use a TVS with suitable reverse stand-off voltageand lower leakage current. and place it as close to the VBATpins as possible. The following figure shows the star structure of the power supply.

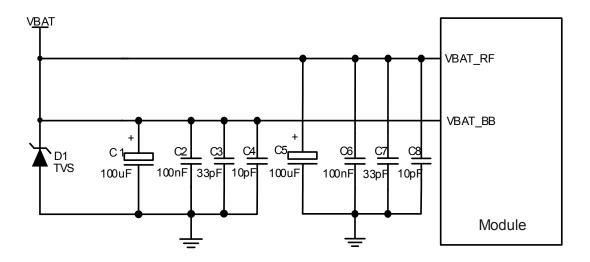


Figure 5: Star Structure of the Power Supply

#### 3.5.3. Monitor the Power Supply

**AT+CBC** command can be used to monitor the VBAT\_BB voltage value. For more details, please refer to **document [2]**.

#### 3.6. Turn on and off Scenarios

#### 3.6.1. Turn on Module Using the PWRKEY Pin

The following table shows the pin definition of PWRKEY.

**Table 7: Pin Definition of PWRKEY** 

Pin Name	Pin No.	Description	DC Characteristics	Comment
PWRKEY	15	Turn on/off the module	Vnorm=0.8V V <sub>IL</sub> max=0.5V	The output voltage is 0.8V because of the diode drop in the Qualcomm chipset.

When BG96 is in power off mode, it can be turned on to normal mode by driving the PWRKEY pin to a low level for at least 500ms. It is recommended to



use an open drain/collector driver to control the PWRKEY.After STATUS pin outputting a high level, PWRKEY pin can be released. A simple reference circuit is illustrated in the following figure.

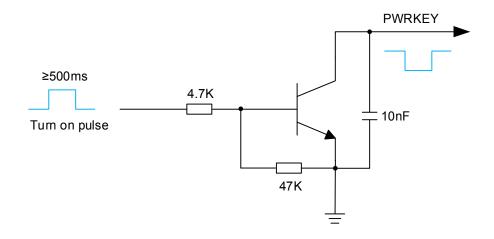


Figure 6: Turn on the Module Using Driving Circuit

Another way to control the PWRKEY is using a button directly. When pressing the key, electrostatic strike may generate from the finger. Therefore, aTVS component is indispensable to be placed nearby the button for ESD protection. A reference circuit is shownin the following figure.

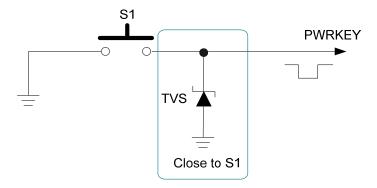


Figure 7: Turn on the Module Using Keystroke

The turn on scenario is illustrated in the following figure.



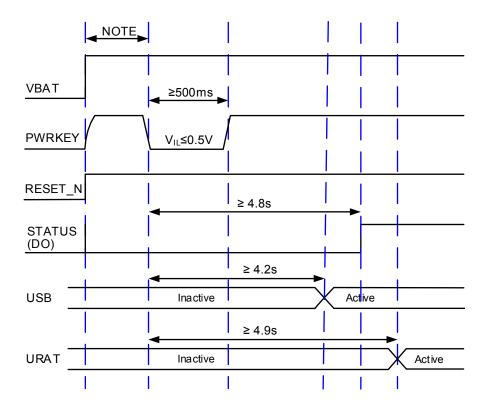


Figure 8: Timing of Turning on Module

#### NOTE

- 1. Make sure that VBAT is stable before pulling down PWRKEY pin. The time between them is no less than 30ms.
- 2. Customers should expect to see ~0.8V on the PWRKEY pin, because of there is pulled up to an internal voltage minus a diode drop in the Qualcomm chipset.

#### 3.6.2. Turn off Module

Either of the following methods can be used to turn off the module:

- Normal power down procedure: Turn off the module using the PWRKEY pin.
- Normal power down procedure: Turn off the module using AT+QPOWDcommand.

#### 3.6.2.1. Turn off Module Using the PWRKEY Pin

Driving the PWRKEY pin to a low level voltagefor at least 650ms, the module will execute power-down procedure after the PWRKEY is released.

The power-down scenario is illustrated in the following figure.



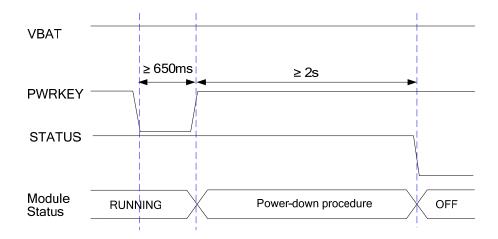


Figure 9: Timing of Turning off Module

#### 3.6.2.2. Turn off Module Using AT Command

It is also a safe way to use **AT+QPOWD**commandto turn off the module, which is similar to turning off the module via PWRKEY pin.

Please refer to document [2] for details about AT+QPOWD command.

#### 3.7. Reset the Module

The RESET\_N pin can be used to reset the module. The module can be reset by driving RESET\_N to a low level voltage for time between 150ms and 460ms.

Table 8: RESET\_N Pin Description

Pin Name	Pin No.	Description	DC Characteristics	Comment
RESET_N	17	Resetsignal of the module	V <sub>IH</sub> max=2.1V V <sub>IH</sub> min=1.3V V <sub>IL</sub> max=0.5V	

The recommended circuit is similar to the PWRKEY control circuit. An open drain/collector driver or button can be used to control the RESET\_N.



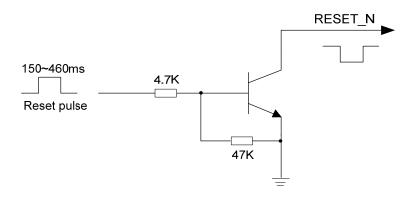


Figure 10: Reference Circuit of RESET\_N by Using Driving Circuit

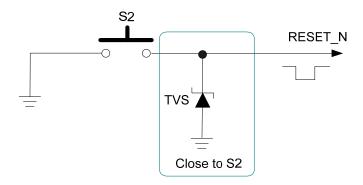


Figure 11: Reference Circuit of RESET\_N by Using Button

The reset scenario is illustrated inthe following figure.



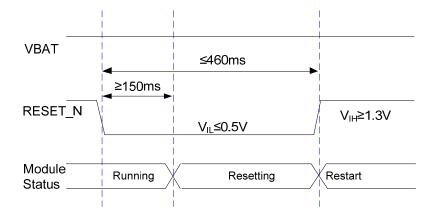


Figure 12: Timing of Resetting Module

#### **NOTES**

1. Use RESET\_N only when turning off the module by **AT+QPOWD**command and PWRKEY pin both failed.

Ensure that there is no large capacitance on PWRKEY and RESET\_N pins.

# 3.8. (U)SIM Interface

The(U)SIM interface circuitrymeets ETSI and IMT-2000 requirements. Both 1.8V and 3.0V (U)SIM cards are supported.

Table 9: Pin Definition of (U)SIM Interface

Pin Name	Pin No.	I/O	Description	Comment
USIM_ PRESENCE	42	DI	(U)SIM card insertion detection	
USIM_VDD	43	РО	Power supply for (U)SIM card	Either 1.8V or 3.0V is supported by the module automatically.
USIM_RST	44	DO	Reset signal of (U)SIM card	
USIM_DATA	45	Ю	Data signal of (U)SIM card	
USIM_CLK	46	DO	Clock signal of (U)SIM card	
USIM_GND	47		Specified ground for (U)SIM card	



BG96 supports (U)SIM card hot-plug via the USIM\_PRESENCEpin. The function supports low level and high level detections, andisdisabled by default. Please refer to *document [2]* about **AT+QSIMDET**command for details.

The following figure shows a reference design of (U)SIM interface with an 8-pin (U)SIM cardconnector.

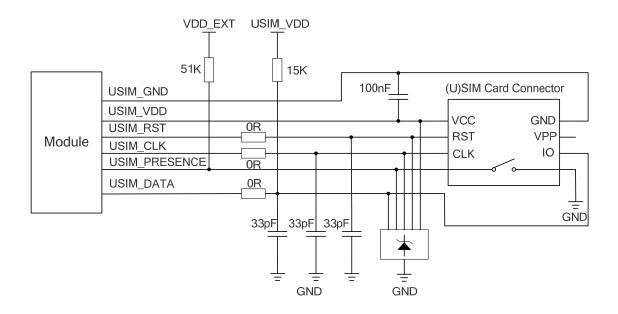


Figure 13: Reference Circuit of (U)SIM Interface withan 8-Pin (U)SIM Card Connector

If (U)SIM card detection function is not needed, please keep USIM\_PRESENCE unconnected. Areference circuit for (U)SIM interface with a 6-pin (U)SIM card connector is illustrated inthe following figure.



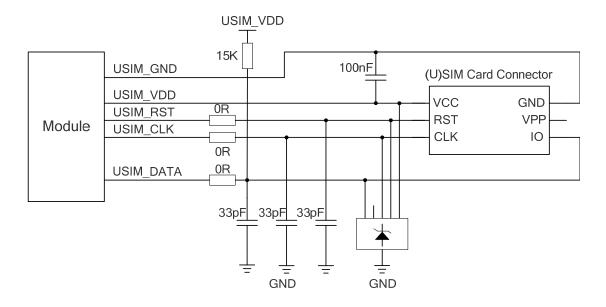


Figure 14: Reference Circuit of (U)SIM Interface with a 6-Pin (U)SIM Card Connector

In order to enhance the reliability and availability of the (U)SIM card in applications, please follow the criteria below in (U)SIM circuit design:

- Keep placement of (U)SIM card connector as close to the module as possible. Keep the trace length as less than 200mm as possible.
- Keep (U)SIM card signals away from RF and VBAT traces.
- Assure the ground between the module and the (U)SIM card connector short and wide. Keep the
  trace width of ground and USIM\_VDD no less than 0.5mm to maintain the same electric potential.
  Make sure the bypass capacitor between USIM\_VDD and USIM\_GND less than 1uF, and place it as
  close to (U)SIM card connector as possible. If the system ground plane is complete, USIM\_GND can
  be connected to the systemground directly.
- To avoid cross-talk between USIM\_DATA and USIM\_CLK, keep them awayfromeach other and shield them with surrounded ground. USIM\_RST should also be ground shielded.
- In order to offer good ESD protection, it is recommended to add a TVSdiode array with parasitic capacitance not exceeding15pF. In order to facilitate debugging, it is recommended to reserve series resistors for the (U)SIM signals of the module. The 33pFcapacitors are used for filtering interference of GSM900MHz. Please note that the (U)SIM peripheral circuit should be close to the (U)SIM cardconnector.
- The pull-up resistor on USIM\_DATA line can improve anti-jamming capability when long layout trace
  and sensitive occasion areapplied, and should be placed close to the (U)SIM cardconnector.



#### 3.9. USB Interface

BG96 contains one integrated Universal Serial Bus (USB) interfacewhich complies with the USB 2.0 specification and supports high-speed (480Mbps) and full-speed (12Mbps)modes. The USB interface is used for AT command communication, data transmission, software debugging and firmware upgrade. The following table shows the pin definition of USB interface.

**Table 10: Pin Definition of USB Interface** 

Pin Name	Pin No.	I/O	Description	Comment
USB_VBUS	8	PI	USB connection detection	Typically 5.0V
USB_DP	9	Ю	USB differential data bus (+)	Require differential impedance of 90Ω
USB_DM	10	Ю	USB differential data bus (-)	Require differential impedance of 90Ω
GND	3		Ground	

For more details about USB 2.0 specification, please visithttp://www.usb.org/home.

The USB interface is recommended to be reserved for firmware upgrade in customers'designs. The following figure shows are ference circuit of USB interface.

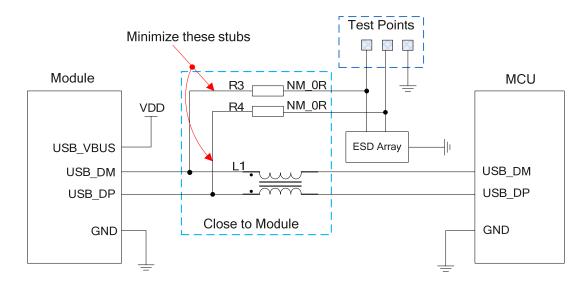


Figure 15: Reference Circuit of USB Interface

A common mode choke L1 is recommended to be added in series between the module and customer's MCU in order to suppress EMI spurious transmission. Meanwhile, the  $0\Omega$  resistors (R3 and R4) should be



added in series between the module and the test points so as to facilitate debugging, and the resistors are not mounted by default. In order to ensure the integrity of USB data line signal, L1/R3/R4 components must be placed close to the module, and also these resistors should be placed close to each other. The extra stubs of trace must be as short as possible.

The following principles should be complied with when design the USB interface, so as to meet USB 2.0 specification.

- It is important to route the USB signal traces as differential pairs with total grounding. The impedance
  of USB differential trace is 90Ω.
- Do not route signal traces under crystals, oscillators, magnetic devices and RF signal traces. It is
  important to route the USB differential traces in inner-layer with ground shielding onnot only upper
  and lower layers but also right and left sides.
- Pay attention to the influence of junction capacitance of ESD protection components on USB data lines. Typically, the capacitance value should be less than 2pF.
- Keep the ESD protection components as close to the USB connector as possible.

**NOTE** 

BG96 module can only be used as a slave device.

#### 3.10. UART Interfaces

The module provides threeUART interfaces: UART1,UART2 and UART3interfaces. The following are theirfeatures.

- UART1 interface supports 9600bps,19200bps,38400bps,57600bps,115200bps,230400bps,460800bps and921600bpsbaud rates, and the default is 115200bps. Itis used for data transmission and AT command communication.
- UART2 interface supports 115200bpsbaud rate, and is used formodule debugging and log output.
- UART3interface supports 115200bps baud rate, and is used for outputting GNSS dataandNMEA sentences.

The following tables show the pin definition of the three UART interfaces.



**Table 11: Pin Definition of UART1Interface** 

Pin Name	Pin No.	I/O	Description	Comment
DTR	30	DI	Data terminal ready. Sleepmode control	1.8V power domain
RXD	34	DI	Receive data	1.8V power domain
TXD	35	DO	Transmit data	1.8V power domain
CTS	36	DO	Clear to send	1.8V power domain
RTS	37	DI	Request to send	1.8V power domain
DCD	38	DO	Data carrier detection	1.8V power domain
RI	39	DO	Ring indicator	1.8V power domain

Table 12: Pin Definition of UART2Interface

Pin Name	Pin No.	I/O	Description	Comment
DBG_RXD	22	DI	Receive data	1.8V power domain
DBG_TXD	23	DO	Transmit data	1.8V power domain

Table 13: Pin Definition of UART3Interface

Pin Name	Pin No.	I/O	Description	Comment
UART3_TXD	27	DO	Transmit data	1.8V power domain
UART3_RXD	28	DI	Receive data	1.8V power domain

The logic levels are described in the following table.



Table 14:Logic Levels of Digital I/O

Parameter	Min.	Max.	Unit
$V_{IL}$	-0.3	0.6	V
$V_{IH}$	1.2	2.0	V
V <sub>OL</sub>	0	0.45	V
V <sub>OH</sub>	1.35	1.8	V

The module provides 1.8V UART interface. A level translator should be used if customers'application is equipped with a 3.3V UART interface. A level translator TXS0108EPWR provided by *Texas Instruments* recommended. The following figure shows a reference design.

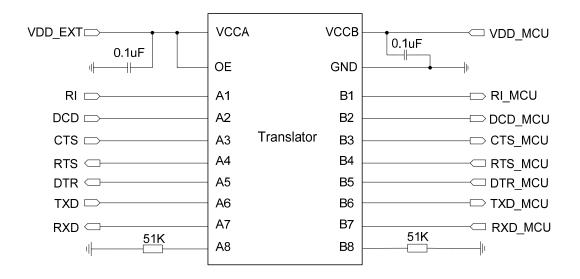


Figure 16: Reference Circuit with Translator Chip

Please visit <a href="http://www.ti.com">http://www.ti.com</a> formore information.

Another example with transistor translation circuit is shown as below.

The circuit design of dotted line section can refer to that of solid line section, in



terms of both module input and output circuit designs, but please pay attention to the direction of connection.

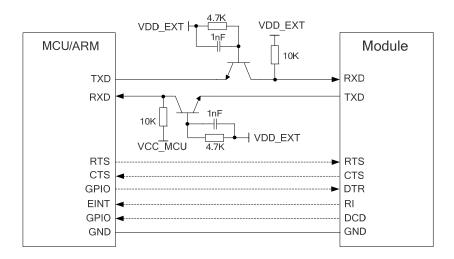


Figure 17: Reference Circuit with Transistor Circuit

NOTE

Transistor circuit solution is not suitable for applications with high baud rates exceeding 460Kbps.

#### 3.11. PCM\* and I2C\* Interfaces

BG96 provides one Pulse Code Modulation (PCM)digital interface and one I2C interface. The following table shows the pin definition of the two interfaces which can be applied on audio codec design.

Table 15: Pin Definition of PCM and I2C Interfaces

Pin Name	Pin No.	I/O	Description	Comment
PCM_CLK*	4	DO	PCM clock output	1.8V power domain
PCM_SYNC*	5	DO	PCMframe synchronization output	1.8V power domain



6	DI	PCM data input	1.8V power domain
7	DO	PCM dataoutput	1.8V power domain
40	OD	I2C serial clock	Require external pull-up to 1.8V
41	OD	I2C serial data	Require external pull-up to 1.8V
	7	7 DO 40 OD	7 DO PCM dataoutput 40 OD I2C serial clock

The following figure shows a reference design of PCM and I2Cinterfaces with an external codec IC.

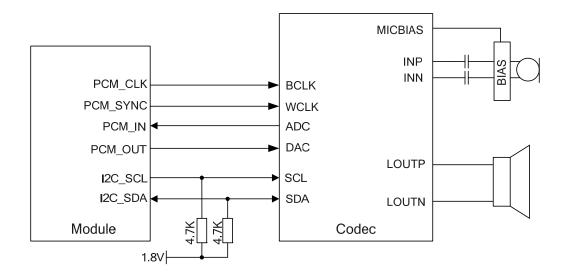


Figure 18: Reference Circuit of PCM Application with Audio Codec

NOTE

"\*" means under development.

#### 3.12. Network Status Indication

BG96 provides one network status indication pin:NETLIGHT. The pin is used to drive a network status indication LED. The following tables describe the pin definition and logic level changes of NETLIGHT in different network activity status.



**Table 16: Pin Definition of NETLIGHT** 

Pin Name	Pin No.	I/O	Description	Comment
NETLIGHT	21	DO	Indicate the module'snetwork activity status	1.8V power domain

**Table 17: Working State of NETLIGHT** 

Pin Name	Logic Level Changes	Network Status
	Flicker slowly (200ms High/1800ms Low)	Network searching
NETHOUT	Flicker slowly (1800ms High/200ms Low)	Idle
NETLIGHT	Flicker quickly (125ms High/125ms Low)	Data transfer is ongoing
	Always high	Voice calling

A reference circuit is shown in the following figure.

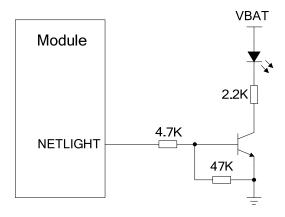


Figure 19: Reference Circuit of the Network Status Indicator



#### **3.13. STATUS**

The STATUS pin is used to indicate the operation status of BG96 module. It will output high level when the module is poweredon.

The following table describes the pin definition of STATUS.

**Table 18: Pin Definition of STATUS** 

Pin Name	Pin No.	I/O	Description		Comment	
STATUS	20	DO	Indicate	the	module's	1.8V power domain
31A103	20	DO	operation status		1.0 v power domain	

The following figure shows a reference circuit of STATUS.

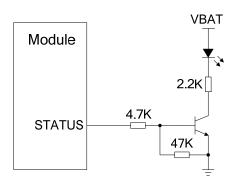


Figure 20: Reference Circuit of STATUS

#### 3.14. Behaviors of RI

AT+QCFG="risignaltype", "physical" command can be used to configure RI behavior.



No matter on which port URC is presented, URC will trigger the behavior of RI pin.

#### NOTE

URC can be outputted from UART port, USB AT port and USB modem port, through configuration via **AT+QURCCFG** command. The default port is USB AT port.

The default behaviors of RI are shown as below.

Table 19: Default Behaviors of RI

State	Response
Idle	RI keeps in high level.
URC	RI outputs 120ms low pulse when new URC returns.

The default RI behaviors can be configured flexibly by **AT+QCFG="urc/ri/ring"** command. For more details, please refer to **document [2]**.

## 3.15. USB\_BOOT Interface

BG96 provides a USB\_BOOT pin. During development or factory production, USB\_BOOT can force the module to boot from USB port for firmware upgrade.



Table 20: Pin Definition of USB\_BOOT Interface

Pin Name	Pin No.	I/O	Description	Comment
				1.8V power domain.
USB_BOOT	75	DI	Force the module to enter into emergency download mode	Active high.
				If unused, keep it open.

The following figure shows a reference circuit of USB\_BOOT interface.

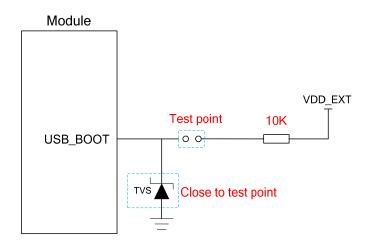


Figure 21: Reference Circuit of USB\_BOOT Interface

NOTE

It is recommended to reserve the above circuit design during application design.

#### 3.16. ADC Interfaces

The module provides two analog-to-digital converter (ADC) interfaces.**AT+QADC=0** command can be used to read the voltage value on ADC0 pin. **AT+QADC=1** command can be used to read the voltage value on ADC1 pin. For more details about these AT commands, please refer to **document [2]**. In order to improve the accuracy of ADCvoltage values, the trace of ADC should be surrounded by ground.



**Table 21: Pin Definition of ADCInterfaces** 

Pin Name	Pin No.	Description
ADC0	24	General purpose analog to digital converter interface
ADC1	2	General purpose analog to digital converter interface

The following table describes the characteristics of ADC interfaces.

**Table 22: Characteristics of ADC Interfaces** 

Parameter	Min.	Тур.	Max.	Unit
ADC0 Voltage Range	0.3		1.8	V
ADC1 Voltage Range	0.3		1.8	V
ADC Resolution			15	bits
ADC Analog-input Bandwidth		100		kHz
ADC Sampling Rate		2.4		MHz

#### **NOTES**

- 1. ADC input voltage must not exceed 1.8V.
- 2. It is prohibited to supply any voltage to ADC pins when VBAT is removed.
- 3. It is recommended to use resistor divider circuit for ADC application, and the divider resistor accuracy should be no less than 1%.

#### 3.17. GPIOInterfaces

The module provides two general-purpose input and output(GPIO) interfaces. **AT+QFWD\*** command can be used toconfigure corresponding GPIO pin's status. For more details about the AT command, please refer to **document [2]**.



**Table 23: Pin Definition of GPIOInterfaces** 

Pin Name	Pin No.	Description
GPIO26	26	General purpose input and output interface
GPIO64	64	General purpose input and output interface

The following table describes the characteristics of GPIOinterfaces.

Table 24:Logic Levels of GPIO interfaces

Parameter	Min.	Max.	Unit
V <sub>IL</sub>	-0.3	0.6	V
V <sub>IH</sub>	1.2	2.0	V
V <sub>OL</sub>	0	0.45	V
V <sub>OH</sub>	1.35	1.8	V

NOTE

"\*" means under development.



# **4** GNSS Receiver

### 4.1. General Description

BG96 includes a fully integrated global navigation satellite system solution that supports Gen8C-Lite of Qualcomm (GPS, GLONASS, BeiDou/Compass, Galileo and QZSS).

BG96 supports standard NMEA-0183 protocol, and outputs NMEA sentences at 1Hz data update rate via USBinterface by default.

By default, BG96 GNSS engine is switched off. It has to be switched on via AT command. For more details about GNSS engine technology and configurations, please refer to *document [3]*.

#### 4.2. GNSS Performance

The following table shows the GNSS performance of BG96.

**Table 25: GNSS Performance** 

Parameter	Description	Conditions	Тур.	Unit
Sensitivity	Cold start	Autonomous	-146	dBm
(GNSS)	Reacquisition	Autonomous	-157	dBm



	Tracking	Autonomous	-157	dBm
	Cold start	Autonomous	31	S
	@open sky	XTRA enabled	11.54	S
TTFF (GNSS)	Warm start	Autonomous	21	S
	@open sky	XTRA enabled	2.52	S
	Hot start	Autonomous	2.7	S
	@open sky	XTRA enabled	1.82	S
Accuracy (GNSS)	CEP-50	Autonomous @open sky	< 2.5	m

#### NOTES

- 1. Tracking sensitivity: the lowest GNSS signal value at the antenna port on which the module can keep on positioning for 3 minutes.
- 2. Reacquisition sensitivity: the lowest GNSS signal value at the antenna port on which the module can fix position again within 3 minutes after loss of lock.
- 3. Cold start sensitivity: the lowest GNSS signal value at the antenna port on which the module fixes position within 3 minutes after executing cold start command.

# 4.3. Layout Guidelines

The following layout guidelines should be taken into account in customers designs.

- Maximize the distance between GNSS antenna and main antenna.
- Digital circuits such as (U)SIM card, USB interface, camera module, display connector and SD card should be kept away from the antennas.
- Use ground vias around the GNSS trace and sensitive analog signal traces to provide coplanar isolation and protection.
- Keep 50Ωcharacteristic impedance for the ANT\_GNSS trace.

Please refer to *Chapter 5* for GNSS antenna reference design and antenna installation information.



# **5** Antenna Interfaces

BG96 includes a main antenna interface and aGNSS antenna interface. The antenna portshave an impedance of  $50\Omega$ .

#### 5.1. MainAntenna Interface

#### 5.1.1. Pin Definition

The pin definition of main antenna interface is shown below.

**Table 26: Pin Definition of Main Antenna Interface** 

Pin Name	Pin No.	I/O	Description	Comment
ANT_MAIN	60	Ю	Main antennainterface	50Ωcharacteristicimpedance

#### **5.1.2. Operating Frequency**

**Table 27: BG96 Operating Frequency** 

3GPP Band	Transr	Transmit		Unit
LTE-FDD B1	1920~1	980	2110~2170	MHz
LTE-FDD	B2,	1010	1930~1990	MHz
PCS1900	1650~	1910	1930~1990	IVITZ
LTE-FDD	1710~1	1785	1805~1880	MHz
B3,DCS1800	1710~	105	1005~1000	IVITIZ
LTE-FDD B4	1710~1	755	2110~2155	MHz



LTE-FDD	824~849	869~894	MHz	
B5,GSM850				
LTE-FDD	880~915	925~960	MHz	
B8,EGSM900	000 010	323 300	IVIFIZ	
LTE-FDD B12	699~716	729~746	MHz	
LTE-FDD B13	777~787	746~756	MHz	
LTE-FDD B18	815~830	860~875	MHz	
LTE-FDD B19	830~845	875~890	MHz	
LTE-FDD B20	832~862	791~821	MHz	
LTE-FDD B25	1850~1915	1930~1995	MHz	
LTE-FDD B26	814~849	859~894	MHz	
LTE-FDD B28	703~748	758~803	MHz	
LTE-TDD B39	1880~1920	1880~1920	MHz	

**Table 28: BG96-M Operating Frequency** 

3GPP Band	Transmit	Receive	Unit
LTE-FDD B1	1920~1980	2110~2170	MHz
LTE-FDD B2	1850~1910	1930~1990	MHz
LTE-FDD B3	1710~1785	1805~1880	MHz
LTE-FDD B4	1710~1755	2110~2155	MHz
LTE-FDD B5	824~849	869~894	MHz
LTE-FDD B8	880~915	925~960	MHz
LTE-FDD B12	699~716	729~746	MHz



LTE-FDD B13	777~787	746~756	MHz
LTE-FDD B18	815~830	860~875	MHz
LTE-FDD B19	830~845	875~890	MHz
LTE-FDD B20	832~862	791~821	MHz
LTE-FDD B25	1850~1915	1930~1995	MHz
LTE-FDD B26	814~849	859~894	MHz
LTE-FDD B28	703~748	758~803	MHz
LTE-TDD B39	1880~1920	1880~1920	MHz

#### 5.1.3. Reference Design of RF Antenna Interface

Areference design of mainantenna padis shown as below. A  $\pi$ -type matching circuit should be reserved for better RF performance, and the  $\pi$ -type matching components (R1/C1/C2) should be placed as close to the antenna as possible. The capacitors are not mounted by default.

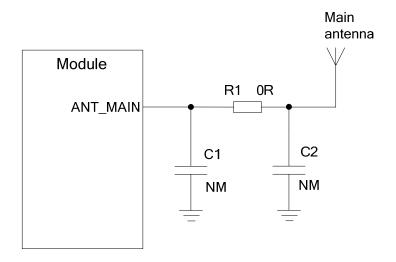


Figure 22: Reference Circuit of RF Antenna Interface

#### 5.1.4. Reference Design of RF Layout

For user's PCB, the characteristic impedance of all RF traces should be controlled as  $50\Omega$ . The impedance of the RF traces is usually determined by



the trace width (W), the materials' dielectric constant, the distance between signal layer and reference ground (H), and the clearance between RF trace and ground(S). Microstrip line or coplanar waveguide line is typically used in RF layout for characteristic impedance control. The following are reference designs of microstrip line or coplanar waveguide linewithdifferent PCB structures.

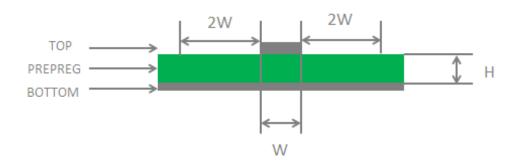


Figure 23: Microstrip Line Designon a 2-layer PCB

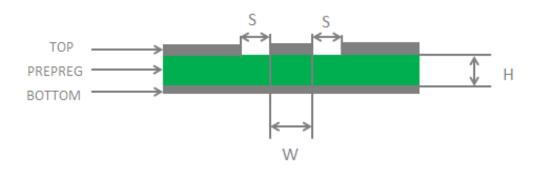


Figure 24: Coplanar Waveguide Line Design on a 2-layer PCB



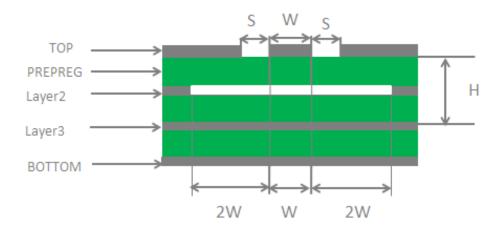


Figure 25: Coplanar Waveguide Line Design on a 4-layer PCB (Layer 3 as Reference Ground)

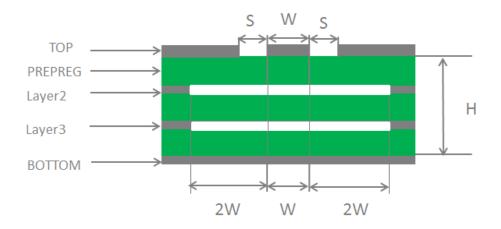


Figure 26: Coplanar Waveguide Line Designon a4-layer PCB (Layer 4 as Reference Ground)

In order to ensure RF performance and reliability, the following principles should be complied with in RF layout design:

- Use impedance simulation tool to control the characteristic impedance of RF traces as  $50\Omega$ .
- The GND pins adjacent to RF pins should not be designed as thermal relief pads, and should be fully connected to ground.
- The distance between the RF pinsand the RFconnectorshould be as short as possible, and all the right angle tracesshould be changed to curved ones.
- There should be clearance area under the signal pin of the antenna connector or solder joint.
- The reference ground of RF traces should be complete. Meanwhile, adding some ground viasaround RF traces and the reference ground could help to improve RF performance. The distance between



the ground via sand RF traces should be no less than two times the width of RF signal traces (2\*W).

For more details about RF layout, please refer to document [4].

#### 5.2. GNSS Antenna Interface

The following tables show the pin definition and frequency specification of GNSS antenna interface.

Table 28: Pin Definition of GNSS Antenna Interface

Pin Name	Pin No.	I/O	Description	Comment
ANT_GNSS	49	Al	GNSS antennainterface	50Ωimpedance

**Table 29: GNSS Frequency** 

Туре	Frequency	Unit
GPS	1575.42±1.023	MHz
GLONASS	1597.5~1605.8	MHz
Galileo	1575.42±2.046	MHz
BeiDou	1561.098±2.046	MHz
QZSS	1575.42	MHz

A reference design of GNSS antenna interfaceis shown as below.



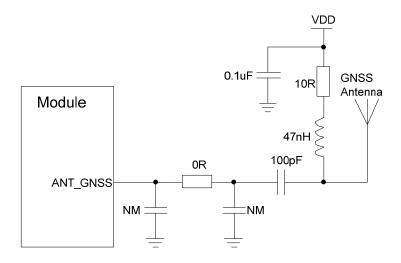


Figure 27: Reference Circuit of GNSS Antenna Interface

#### **NOTES**

- 1. An external LDO can be selected to supply power according to the active antenna requirement.
- 2. If the module is designed with a passive antenna, then the VDD circuit is not needed.

#### 5.3. Antenna Installation

#### 5.3.1. Antenna Requirements

The following table shows the requirements on main antennaand GNSS antenna.



**Table 30: Antenna Requirements** 

Antenna Type	Requirements		
	Frequency range: 1559MHz ~1609MHz		
	Polarization: RHCP or linear		
1)	VSWR: <2 (Typ.)		
GNSS <sup>1)</sup>	Passive antenna gain: >0dBi		
	Active antenna noise figure: <1.5dB		
	Active antenna gain: > 0dBi		
	Active antenna embedded LNA gain: < 17dB		
	VSWR: ≤2		
	Efficiency: > 30%		
	Max Input Power (W): 50		
	Input Impedance (Ω): 50		
	Cable Insertion Loss: <1dB		
LTE/GSM	(LTE B5/B8/B12/B13/B18/B19/B20/B26/B28,		
	GSM850/EGSM900)		
	Cable Insertion Loss: <1.5dB		
	(LTE B1/B2/B3/B4/B25/B39,DCS1800/PCS1900)		

#### NOTE

#### 5.3.2. Recommended RF Connector for Antenna Installation

If RF connector is used for antenna connection, it is recommended to use the U.FL-R-SMTconnector provided by *HIROSE*.

<sup>&</sup>lt;sup>1)</sup>It is recommended to use a passive GNSS antenna when LTE B13 or B14 is supported, as the use of active antenna may generate harmonics which will affect the GNSS performance.



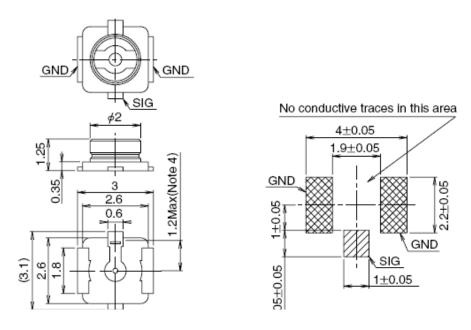


Figure 28: Dimensions of the U.FL-R-SMT Connector (Unit: mm)

U.FL-LP serial connectors listed in the following figure can be used to match the U.FL-R-SMT.

	U.FL-LP-040	U.FL-LP-066	U.FL-LP(V)-040	U.FL-LP-062	U.FL-LP-088
Part No.	3	SE S	87 3.4 93 93 93 93	87	5
Mated Height	2.5mm Max. (2.4mm Nom.)	2.5mm Max. (2.4mm Nom.)	2.0mm Max. (1.9mm Nom.)	2.4mm Max. (2.3mm Nom.)	2.4mm Max. (2.3mm Nom.)
Applicable cable	Dia. 0.81mm Coaxial cable	Dia. 1.13mm and Dia. 1.32mm Coaxial cable	Dia. 0.81mm Coaxial cable	Dia. 1mm Coaxial cable	Dia. 1.37mm Coaxial cable
Weight (mg)	53.7	59.1	34.8	45.5	71.7
RoHS			YES		

Figure 29: Mechanicals of U.FL-LP Connectors



The following figure describes the space factor of mated connector.

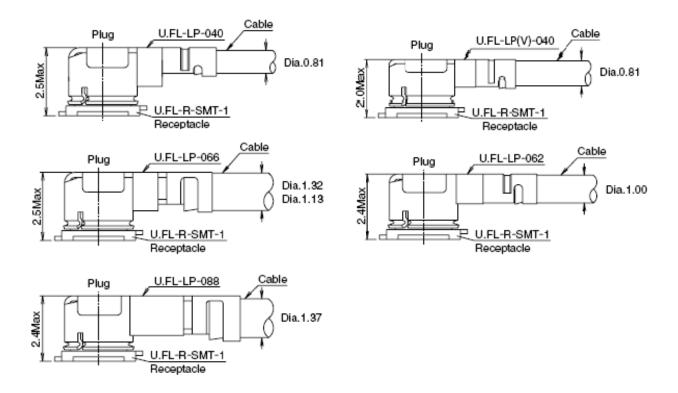


Figure 30:Space Factor of Mated Connector (Unit: mm)

For more details, please visithttp://www.hirose.com.



# **6** Electrical, Reliability and RadioCharacteristics

# 6.1. Absolute Maximum Ratings

Absolute maximum ratings for power supply and voltage on digital and analog pins of the module are listed in the following table.

**Table 31: Absolute Maximum Ratings** 

Parameter	Min.	Max.	Unit
VBAT_BB	-0.5	6	V
VBAT_RF	-1.2	6	V
USB_VBUS	-0.3	5.5	V
Voltage at Digital Pins	-0.3	2.3	V

# 6.2. Power Supply Ratings



**Table 32: Power Supply Ratings** 

Parameter	Description	Conditions	Min.	Тур.	Max.	Unit
VBAT	VBAT_BB and VBAT_RF	The actual input voltages must stay between the minimum and maximum values.	3.3	3.8	4.3	V
I <sub>VBAT</sub>	Peak supply current (during transmissionslot)	Maximum power control level on EGSM900		1.8	2.0	А
USB_VBUS	USB detection		3.0	5.0	5.25	V

## 6.3. Operation and StorageTemperatures

The operation and storagetemperatures of the modulearelisted in the following table.

**Table 33: Operation and StorageTemperatures** 

Parameter	Min.	Тур.	Max.	Unit
OperationTemperature Range <sup>1)</sup>	-35	+25	+75	°C
Extended Temperature Range <sup>2)</sup>	-40		+85	°C
Storage Temperature Range	-40		+90	°C

#### **NOTES**

- 1. <sup>1)</sup>Withinoperation temperature range, the module is 3GPP compliant.
- 2. <sup>2)</sup>Within extended temperature range, the module remains the ability to establish and maintain a voice, SMS, data transmission, emergency call, etc. There is no unrecoverable malfunction. There are also no effects on radio spectrum and no harm to radio network. Only one or more parameters like P<sub>out</sub> might reduce in their value and exceed the specified tolerances. When the temperature



returns to the normal operating temperature levels, the module will meet 3GPP specifications again.

# 6.4. Current Consumption

The following table shows current consumption of BG96 module.

**Table 34: BG96Current Consumption** 

Parameter	Description	Conditions	Typ. <sup>1)</sup>	Unit
	Leakage Current	Power off mode	8	uA
	PSM	Power Saving Mode @Real Network	10	uA
	Rock bottom Sleep <sup>2)</sup>	AT+CFUN=0@Sleep State	0.8	mA
		DRX=1.28s @ Instrument	1.5	mA
		DRX=1.28s @ Instrument	1.96	mA
	Sleep State 3)	e-I-DRX=20.48s @ Instrument	1.2	mA
		e-I-DRX=20.48s @ Instrument	1.1	mA
I <sub>VBAT</sub>		@Real 2G Network	1.2 m/A 1.1 m/A 2.0 m/A 15 m/A	mA
.5		DRX=1.28s @ Instrument	15	mA
		DRX=1.28s @Instrument	15	mA
	Idle State	e-I-DRX=20.48s @ Instrument	15	mA
		e-I-DRX=20.48s @ Instrument	15	mA
		@Real 2G Network	15	mA
	LTE Cat M1	LTE-FDD B1 @23.31dBm	220	mA
	(GNSS OFF)	LTE-FDD B2 @23.05dBm	208	mA



	LTE-FDD B3 @23.09dBm	214	mA
	LTE-FDD B4 @23.19dBm	214	mA
	LTE-FDD B5 @23.22dBm	210	mA
	LTE-FDD B8 @21.83dBm	203	mA
	LTE-FDD B12 @21.88dBm	215	mA
	LTE-FDD B13 @21.96dBm	197	mA
	LTE-FDD B18 @23.04dBm	212	mA
	LTE-FDD B19 @23.13dBm	211	mA
	LTE-FDD B20 @23.07dBm	209	mA
	LTE-FDD B25 @23.01dBm	211	mA
	LTE-FDD B26 @22.81dBm	214	mA
	LTE-FDD B28 @22.52dBm	215	mA
	LTE-TDD B39 @TBD	TBD	mA
	LTE-FDD B1 @22.8dBm	170	mA
	LTE-FDD B2 @22.6dBm	171	mA
	LTE-FDD B3 @22.6dBm	161	mA
LTE Cat NB1 data transfer	LTE-FDD B4 @22.6dBm	161	mA
(GNSS OFF)	LTE-FDD B5 @22.9dBm	156	mA
	LTE-FDD B8 @22.7dBm	170	mA
	LTE-FDD B12 @23dBm	170	mA
	LTE-FDD B13 @22.9dBm	167	mA



	LTE-FDD B18 @23.1dBm	159	mA
	LTE-FDD B19 @22.9dBm	155	mA
	LTE-FDD B20 @22.7dBm	157	mA
	LTE-FDD B25 @23dBm	165	mA
	LTE-FDD B26 @22.8dBm	162	mA
	LTE-FDD B28 @22.5dBm	163	mA
	GSM850 4UL1DL @30.17dBm	575	mA
	GSM850 3UL2DL @32dBm	533	mA
	GSM850 2UL3DL @32.74dBm	402	mA
	GSM850 1UL4DL @32.52dBm	220	mA
	EGSM900 4UL1DL @30.54dBm	586	mA
	EGSM900 3UL2DL @31.36dBm	556	mA
	EGSM9002UL3DL @32.62dBm	399	mA
GPRS data transfer	EGSM9001UL4DL @32.75dBm	228	mA
(GNSS OFF)	DCS18004UL1DL @29.81dBm	543	mA
	DCS18003UL2DL @30.09dBm	426	mA
	DCS18002UL3DL @30.1dBm	301	mA
	DCS18001UL4DL @30.34dBm	182	mA
	PCS1900 4UL1DL @29.64dBm	516	mA
	PCS1900 3UL2DL @29.86dBm	404	mA
	PCS1900 2UL3DL @29.7dBm	281	mA



	PCS1900 1UL4DL @29.94dBm	171	mA
	GSM850 4UL1DL @26.02dBm	403	mA
	GSM850 3UL2DL @26.11dBm	312	mA
	GSM850 2UL3DL @26.57dBm	224	mA
	GSM850 1UL4DL @26.92dBm	136	mA
	EGSM900 4UL1DL @25.92dBm	391	mA
	EGSM900 3UL2DL @26.11dBm	301	mA
	EGSM9002UL3DL @26.16dBm	217	mA
EDGE data	a EGSM9001UL4DL @26.88dBm	133	mA
transfer (GNSS OF	FF) DCS1800 4UL1DL @24.7dBm	373	mA
	DCS18003UL2DL @25.97dBm	286	mA
	DCS18002UL3DL @25.03dBm	208	mA
	DCS18001UL4DL @25.03dBm	127	mA
	PCS1900 4UL1DL @24.92dBm	375	mA
	PCS1900 3UL2DL @24.86dBm	288	mA
	PCS1900 2UL3DL @25.17dBm	207	mA
	PCS1900 1UL4DL @25.31dBm	127	mA
LTE Voice (GNSS OF	Voice @LTE Cat M1 network	108	mA

### NOTES

- 1. 1) means the average value.
- 2. <sup>2)</sup>means the operation is performed with **AT+CFUN=0** and **AT+QSLCK=1**(DTR pin at high level).
- $^{3)}$ Sleep state with UART connected and USB disconnected. The module can enter into sleep state



through executing AT+QSCLK=1 command via UART interface and then controlling the module's DTR pin. For details, please refer to *Chapter 3.4.4*.

**Table 35: GNSSCurrent Consumption** 

Description	Conditions	Тур.	Unit
Searching	Cold Start @Passive Antenna	41.7	mA
(AT+CFUN=0)	Lost State @Passive Antenna	42	mA
Tracking	Instrument Environment	21.7	mA
(AT+CFUN=0)	Open Sky @Passive Antenna	36	mA
	Open Sky @Active Antenna	35	mA

### 6.5. RF Output Power

The following table shows the RF output power of BG96 module.

**Table 36: RF Output Power** 

Frequency	Max.	Min.
LTE-FDD		
B1/B2/B3/B4/B5/B8/B12/B13/B18/B19/B20/B25/	23dBm±2dB	<-39dBm
B26/B28		
LTE-TDD B39	23dBm±2dB	<-39dBm
GSM850/EGSM900	33dBm±2dB	5dBm±5dB
DCS1800/PCS1900	30dBm±2dB	0dBm±5dB



GSM850/EGSM900 (8-PSK)	27dBm±3dB	5dBm±5dB
DCS1800/PCS1900 (8-PSK)	26dBm±3dB	0dBm±5dB

### 6.6. RF Receiving Sensitivity

The following table shows the conducted RF receiving sensitivity of BG96 module.

Table 37: BG96 Conducted RF Receiving Sensitivity

Network	Pand	Drimon, Diversity		Sensi	tivity(dBm)		
Network	Dallu	Primary	Diversity	Cat M1/3GPP	Cat NB1 <sup>1)</sup> /3GPP		
	LTE-FDD B1			-107.0/-102.7	-112.5/-107.5		
	LTE-FDD B2	_		-106.7/-100.3	-112.5/-107.5		
	LTE-FDD B3	_		-106.8/-99.3	-113/-107.5		
	LTE-FDD B4	_		-106.9/-102.3	-112.5/-107.5		
	LTE-FDD B5	Not Supported Support		-107.0/-100.8	-114/-107.5		
	LTE-FDD B8		Not	-107.3/-99.8	-113/-107.5		
LTE	LTE-FDD B12		Supported	2 Supported		-107.7/-99.3	-113.5/-107.5
	LTE-FDD B13		Supported	-106.5/-99.3	-112/-107.5		
	LTE-FDD B18			-107.5/-102.3	-113.5/-107.5		
	LTE-FDD B19			-107.1/-102.3	-114/-107.5		
	LTE-FDD B20		-107.2/-99.8	-114/-107.5			
	LTE-FDD B25			-106/-100.3	-112/-107.5		
	LTE-FDD B26			-107.1/-100.3	-113/-107.5		



	LTE-FDD B28			-107.2/-100.8	-113/-107.5
	LTE-TDD B39	-		TBD /-103	Not Supported
Notwork	work Band Primary Diversity		Sensi	itivity (dBm)	
Network	Band	Primary Diversity	GS	SM/3GPP	
	GSM850/EGSM900		Not		109/-102
GSM	DCS1800/PCS1900	Supported	Supported	-10	08.5/-102

Table 38: BG96-M Conducted RF Receiving Sensitivity

Network	Pand	Drimory	Disconsitu	Sensitivity(dBm)
Network	Бапа	Primary	Diversity	Cat M1/3GPP
	LTE-FDD B1			-107.0/-102.7
	LTE-FDD B2			-106.7/-100.3
	LTE-FDD B3			-106.8/-99.3
	LTE-FDD B4			-106.9/-102.3
	LTE-FDD B5	Supported	Not Supported	-107.0/-100.8
	LTE-FDD B8			-107.3/-99.8
LTE	LTE-FDD B12			-107.7/-99.3
LIE	LTE-FDD B13			-106.5/-99.3
	LTE-FDD B18			-107.5/-102.3
	LTE-FDD B19			-107.1/-102.3
	LTE-FDD B20			-107.2/-99.8
	LTE-FDD B25			-106/-100.3
	LTE-FDD B26			-107.1/-100.3
	LTE-FDD B28			-107.2/-100.8



LTE-TDD B39	TBD /-103



<sup>1)</sup>LTE Cat NB1 receiving sensitivity without repetitions.

### 6.7. Electrostatic Discharge

The module is not protected against electrostatics discharge (ESD) in general. Consequently, it is subject to ESD handling precautions that typically apply to ESD sensitive components. Proper ESD handling and packaging procedures must be applied throughout the processing, handling and operation of any application that incorporates the module.

The following table shows the electrostatic discharge characteristics of BG96 module.

**Table 38: Electrostatic Discharge Characteristics** 

Tested Points	Contact Discharge	Air Discharge	Unit
VBAT, GND	±10	±15	kV
Main/GNSS Antenna Interfaces	±10	±15	kV



### 7 Mechanical Dimensions

This chapter describes the mechanical dimensions of the module. All dimensions are measured in mm, and the tolerances for dimensions without tolerance values are ±0.05mm.

### 7.1. Mechanical Dimensions of the Module

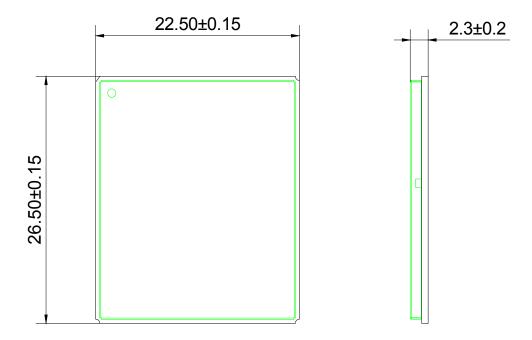


Figure 31: Module Top and Side Dimensions



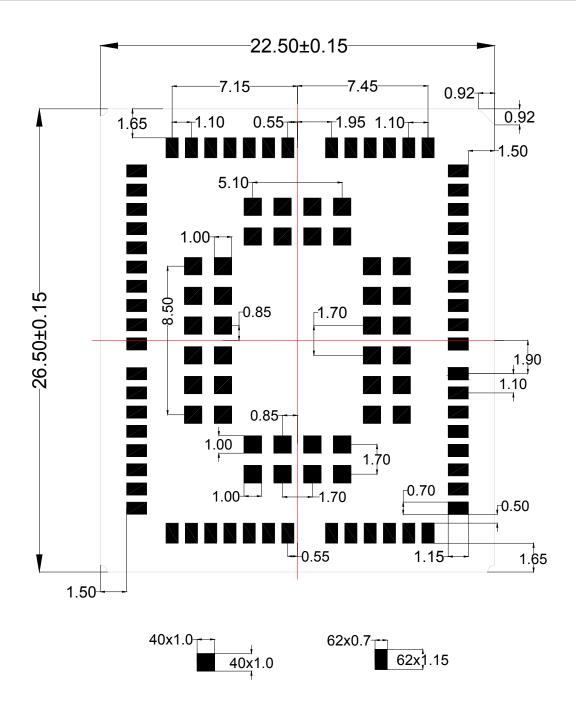


Figure 32: Module Bottom Dimensions (Bottom View)



### 7.2. Recommended Footprint

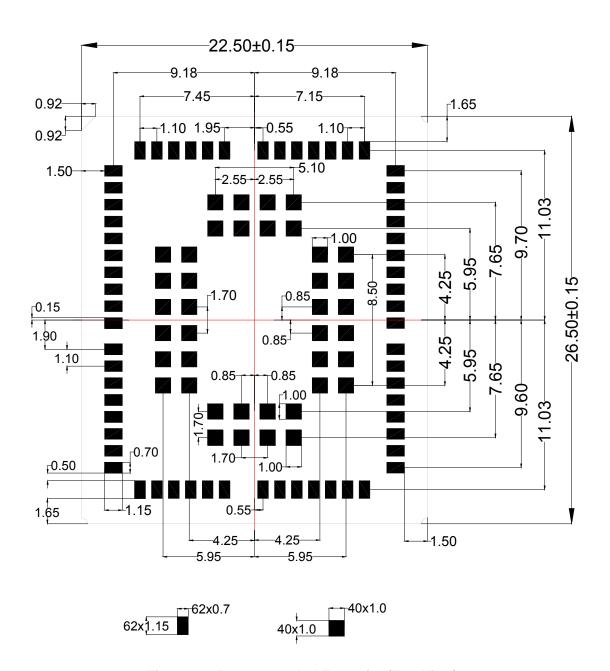


Figure 33: Recommended Footprint (Top View)

### **NOTES**

1. For easy maintenance of the module, please keep about 3mm between the module and other components onthe host PCB.

All reserved pins must be kept open.



For stencil design requirements of the module, please refer to **document [5]**.

### 7.3. Design Effect Drawings of the Module



Figure 34: Top View of the Module

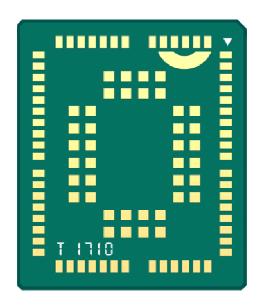


Figure 35: Bottom View of the Module



### **NOTE**

These are design effect drawings of BG96 module. For more accurate pictures, please refer to the module that you get from Quectel.



# 8 Storage, Manufacturing and Packaging

### 8.1. Storage

BG96 is stored in avacuum-sealed bag. It is rated at MSL 3, and its storage restrictions are listed below.

- 1. Shelf life in the vacuum-sealed bag: 12 months at <40°C/90%RH.
- 2. After the vacuum-sealed bag is opened, devices that will be subjected to reflow soldering or other high temperature processes must be:
  - Mounted within 168 hours at the factory environment of ≤30°C/60%RH.
  - Stored at <10%RH.</li>
- 3. Devices require baking before mounting, if any circumstance below occurs.
  - When the ambient temperature is 23°C±5°Cand the humidity indication card shows the humidity is >10% before opening the vacuum-sealed bag.
  - Device mounting cannot be finished within 168 hours at factory conditions of ≤30°C/60% RH.
  - Stored at >10% RH after the vacuum-sealed bag is opened.
- 4. If baking is required, devices may be baked for 8 hours at 120°C±5°C.

#### **NOTE**

As the plastic package cannot be subjected to high temperature, it should be removed from devices before high temperature (120°C) baking. If shorter baking time is desired, please refer to *IPC/JEDECJ-STD-033* for baking procedure.



### 8.2. Manufacturing and Soldering

Push the squeegee to apply the solder paste on the surface of stencil, thus making the paste fill the stencil openings and then penetrate to the PCB. The force on the squeegee should be adjusted properlyso as to produce a clean stencil surface on a single pass. To ensure the module soldering quality, thethickness of stencil for the module is recommended to be 0.18mm~0.20mm. For more details, please refer to **document [5]**.

It is suggested that the peak reflow temperature is 240~245°C, and the absolute maximum reflow temperature is 245°C. To avoid damage to the module caused by repeated heating, it is strongly recommended that the module should be mounted after reflow soldering for the other side of PCB has been completed. The recommended reflow soldering thermal profile (lead-free reflow soldering) and related parameters are shown below.

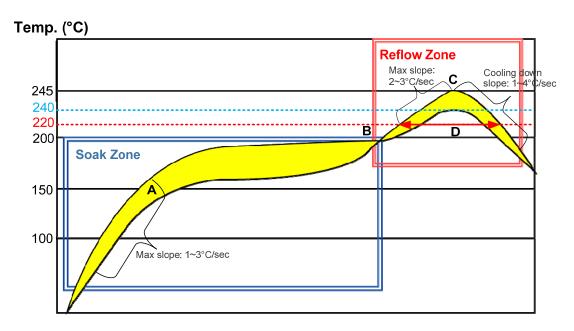


Figure 36: Recommended Reflow Soldering Thermal Profile

**Table 39: Recommended Thermal Profile Parameters** 

Factor	Recommendation
Soak Zone	

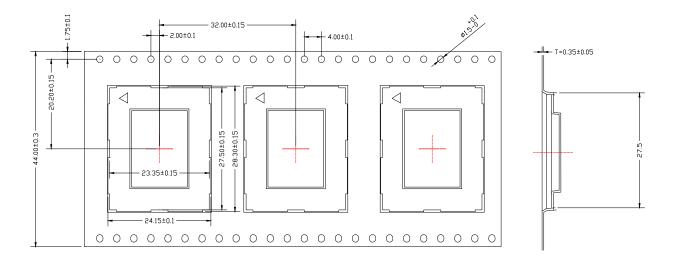


Max slope	1 to 3°C/sec
Soak time (between A and B: 150°C and 200°C)	60 to 120 sec
Reflow Zone	
Max slope	2 to 3°C/sec
Reflow time (D: over 220°C)	40 to 60 sec
Max temperature	240°C ~ 245°C
Cooling down slope	1 to 4°C/sec
Reflow Cycle	
Max reflow cycle	1

### 8.3. Packaging

BG96 ispackaged in a vacuum-sealed bag which is ESD protected. The bag should not be opened until the devices are ready to be soldered onto the application.

The reel is 330mm in diameter and each reel contains 250 modules. The following figures show the packaging details, measured in mm.





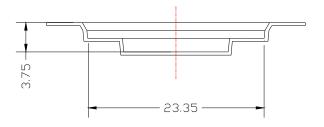


Figure 37: Tape Dimensions

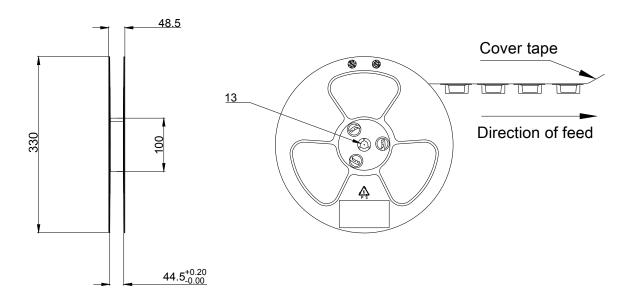


Figure 38: ReelDimensions

Table 40: Reel Packaging

Model Name	MOQ for MP	MinimumPackage: 250pcs	Minimum Packagex4=1000pcs
BG96	250pcs	Size: 370mm× 350mm × 56mm N.W: 1.0kg G.W: 1.71kg	Size: 380mm× 250mm× 365mm N.W: 4.0kg G.W: 7.16kg



## 9 Appendix A References

#### **Table 41: Related Documents**

SN	Document Name	Remark
[1]	Quectel_UMTS&LTE_EVB_User_Guide	UMTS&LTEEVB User Guide
[2]	Quectel_BG96_AT_Commands_Manual	BG96 AT Commands Manual
[3]	Quectel_BG96_GNSS_AT_Commands_Manual	BG96 GNSS AT Commands Manual
[4]	Quectel_RF_Layout_Application_Note	RF Layout Application Note
[5]	Quectel_Module_Secondary_SMT_User_Guide	Module Secondary SMT User Guide

**Table 42: Terms and Abbreviations** 

Abbreviation	Description
AMR	Adaptive Multi-rate
bps	Bits Per Second
CHAP	Challenge Handshake Authentication Protocol
CS	Coding Scheme
CTS	Clear To Send
DFOTA	Delta Firmware Upgrade Over The Air
DL	Downlink
DTR	Data Terminal Ready
DTX	Discontinuous Transmission
e-I-DRX	Extended Idle Mode Discontinuous Reception
EPC	Evolved Packet Core



ESD	Electrostatic Discharge
FDD	Frequency Division Duplex
FR	Full Rate
GMSK	Gaussian Minimum Shift Keying
GSM	Global System for Mobile Communications
HSS	Home Subscriber Server
I/O	Input/Output
Inorm	Normal Current
LED	Light Emitting Diode
LNA	Low Noise Amplifier
LTE	Long Term Evolution
MO	Mobile Originated
MS	Mobile Station (GSM engine)
MT	Mobile Terminated
PAP	Password Authentication Protocol
PCB	Printed Circuit Board
PDU	Protocol Data Unit
PPP	Point-to-Point Protocol
PSM	Power Saving Mode
RF	Radio Frequency
RHCP	Right Hand Circularly Polarized
Rx	Receive
SISO	Single Input Single Output
SMS	Short Message Service
TDD	Time Division Duplexing



TX	Transmitting Direction
UL	Uplink
UE	User Equipment
URC	Unsolicited Result Code
(U)SIM	(Universal) Subscriber Identity Module
Vmax	Maximum Voltage Value
Vnorm	Normal Voltage Value
Vmin	Minimum Voltage Value
V <sub>IH</sub> max	Maximum Input High Level Voltage Value
V <sub>IH</sub> min	Minimum Input High Level Voltage Value
V <sub>IL</sub> max	Maximum Input Low Level Voltage Value
V <sub>IL</sub> min	Minimum Input Low Level Voltage Value
V <sub>I</sub> max	Absolute Maximum Input Voltage Value
V <sub>I</sub> min	Absolute Minimum Input Voltage Value
V <sub>OH</sub> max	Maximum Output High Level Voltage Value
V <sub>OH</sub> min	Minimum Output High Level Voltage Value
V <sub>OL</sub> max	Maximum Output Low Level Voltage Value
V <sub>OL</sub> min	Minimum Output Low Level Voltage Value
VSWR	Voltage Standing Wave Ratio



## 10 Appendix B GPRS Coding Schemes

**Table 43: Description of Different Coding Schemes** 

Scheme	CS-1	CS-2	CS-3	CS-4
Code Rate	1/2	2/3	3/4	1
USF	3	3	3	3
Pre-coded USF	3	6	6	12
Radio Block excl.USF and BCS	181	268	312	428
BCS	40	16	16	16
Tail	4	4	4	-
Coded Bits	456	588	676	456
Punctured Bits	0	132	220	-
Data Rate Kb/s	9.05	13.4	15.6	21.4



### 11 Appendix C GPRS Multi-slot Classes

Twenty-nine classes of GPRS multi-slot modes are defined for MS in GPRS specification. Multi-slot classes are product dependent, and determine the maximum achievable data rates in both the uplink and downlink directions. Written as 3+1 or 2+2, the first number indicates the amount of downlink timeslots, while the second number indicates the amount of uplink timeslots. The active slots determine the total number of slots the GPRS device can use simultaneously for both uplink and downlink communications.

The description of different multi-slot classes is shown in the following table.

**Table 44: GPRS Multi-slot Classes** 

Multislot Class	Downlink Slots	Uplink Slots	Active Slots
1	1	1	2
2	2	1	3
3	2	2	3
4	3	1	4
5	2	2	4
6	3	2	4
7	3	3	4
8	4	1	5
9	3	2	5
10	4	2	5
11	4	3	5
12	4	4	5
13	3	3	NA
14	4	4	NA



15	5	5	NA	
16	6	6	NA	
17	7	7	NA	
18	8	8	NA	
19	6	2	NA	
20	6	3	NA	
21	6	4	NA	
22	6	4	NA	
23	6	6	NA	
24	8	2	NA	
25	8	3	NA	
26	8	4	NA	
27	8	4	NA	
28	8	6	NA	
29	8	8	NA	
30	5	1	6	
31	5	2	6	
32	5	3	6	
33	5	4	6	



# 12 Appendix D EDGE Modulation and Coding Schemes

**Table 45: EDGE Modulation and Coding Schemes** 

Coding Schemes	Modulation	Coding Family	1 Timeslot	2 Timeslot	4 Timeslot
CS-1:	GMSK	1	9.05kbps	18.1kbps	36.2kbps
CS-2:	GMSK	1	13.4kbps	26.8kbps	53.6kbps
CS-3:	GMSK	1	15.6kbps	31.2kbps	62.4kbps
CS-4:	GMSK	1	21.4kbps	42.8kbps	85.6kbps
MCS-1	GMSK	С	8.80kbps	17.60kbps	35.20kbps
MCS-2	GMSK	В	11.2kbps	22.4kbps	44.8kbps
MCS-3	GMSK	А	14.8kbps	29.6kbps	59.2kbps
MCS-4	GMSK	С	17.6kbps	35.2kbps	70.4kbps
MCS-5	8-PSK	В	22.4kbps	44.8kbps	89.6kbps
MCS-6	8-PSK	А	29.6kbps	59.2kbps	118.4kbps
MCS-7	8-PSK	В	44.8kbps	89.6kbps	179.2kbps
MCS-8	8-PSK	A	54.4kbps	108.8kbps	217.6kbps
MCS-9	8-PSK	A	59.2kbps	118.4kbps	236.8kbps